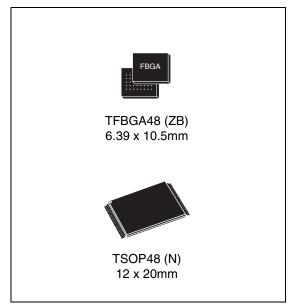


M28W640FCT M28W640FCB

64 Mbit (4Mbx16, Boot Block) 3V Supply Flash memory

Feature summary

- Supply voltage
 - V_{DD} = 2.7V to 3.6V Core Power Supply
 - V_{DDO}= 1.65V to 3.6V for Input/Output
 - V_{PP} = 12V for fast Program (optional)
- Access times: 70, 85, 90,100ns
- Programming time:
 - 10µs typical
 - Double Word Programming Option
 - Quadruple Word Programming Option
- Common Flash Interface
- Memory blocks
 - Parameter Blocks (Top or Bottom location)
 - Main Blocks
- Block locking
 - All blocks locked at Power Up
 - Any combination of blocks can be locked
 - WP for Block Lock-Down
- Security
 - 128 bit user Programmable OTP cells
 - 64 bit unique device identifier
- Automatic standby mode
- Program and Erase Suspend
- 100,000 program/erase cycles per block
- Electronic signature
 - Manufacturer code: 20h
 - Top device code, M28W640FCT: 8848h
 - Bottom device code, M28W640FCB: 8849h



- Packages
 - ECOPACK® compliant

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1 Summary description

The M28W640FCT and M28W640FCB are 64 Mbit (4 Mbit x 16) non-volatile Flash memories that can be erased electrically at block level and programmed in-system on a Word-by-Word basis using a 2.7V to 3.6V V_{DD} supply for the circuitry and a 1.65V to 3.6V V_{DDQ} supply for the Input/Output pins. An optional 12V V_{PP} power supply is provided to speed up customer programming.

The devices feature an asymmetrical blocked architecture. They have an array of 135 blocks: 8 Parameter Blocks of 4 KWord and 127 Main Blocks of 32 KWord. The M28W640FCT has the Parameter Blocks at the top of the memory address space while the M28W640FCB locates the Parameter Blocks starting from the bottom. The memory maps are shown in *Figure 4: Block addresses*.

The M28W640FCT and M28W640FCB feature an instant, individual block locking scheme that allows any block to be locked or unlocked with no latency, enabling instant code and data protection. All blocks have three levels of protection. They can be locked and locked-down individually preventing any accidental programming or erasure. There is an additional hardware protection against program and erase. When $V_{PP} \leq V_{PPLK}$ all blocks are protected against program or erase. All blocks are locked at Power Up.

Each block can be erased separately. Erase can be suspended in order to perform either read or program in any other block and then resumed. Program can be suspended to read data in any other block and then resumed. Each block can be programmed and erased over 100,000 cycles.

The device includes a 192 bit Protection Register to increase the protection of a system design. The Protection Register is divided into a 64 bit segment and a 128 bit segment. The 64 bit segment contains a unique device number written by Numonyx, while the second one is one-time-programmable by the user. The user programmable segment can be permanently protected. *Figure 5*, shows the Protection Register Memory Map.

Program and Erase commands are written to the Command Interface of the memory. An onchip Program/Erase Controller takes care of the timings necessary for program and erase operations. The end of a program or erase operation can be detected and any error conditions identified. The command set required to control the memory is consistent with JEDEC standards.

The memory is offered in TSOP48 (12×20 mm) and TFBGA48 (6.39×10.5 mm, 0.75mm pitch) packages and is supplied with all the bits erased (set to '1').

In order to meet environmental requirements, Numonyx offers the M28W640FCT and M28W640FCB in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second Level Interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97.

The maximum ratings related to soldering conditions are also marked on the inner box label.

Figure 1. Logic diagram

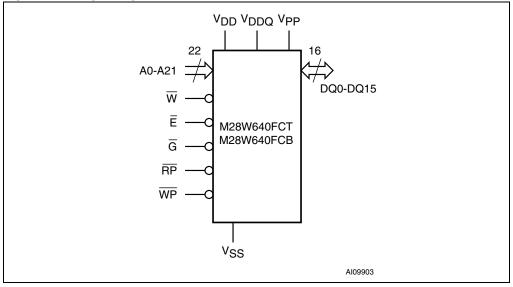
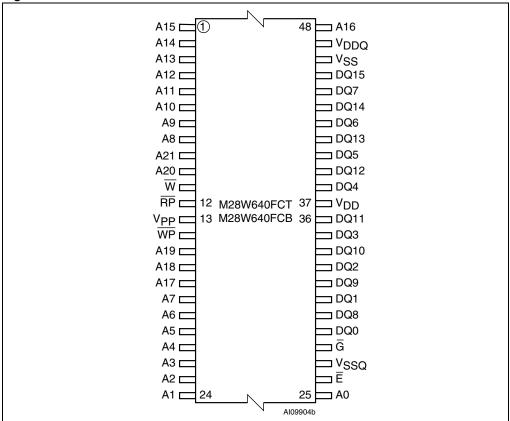


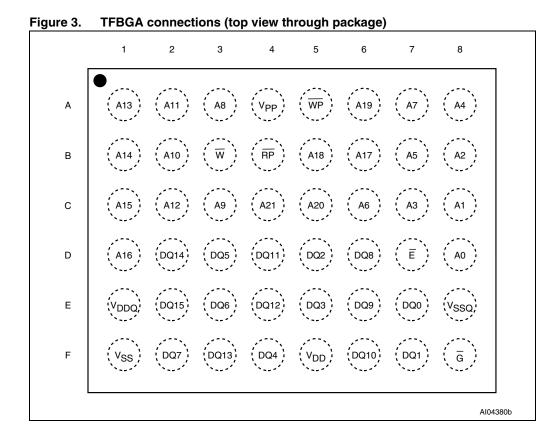
Table 1. Signal names

A0-A21	Address Inputs
DQ0-DQ15	Data Input/Output
Ē	Chip Enable
G	Output Enable
\overline{W}	Write Enable
RP	Reset
WP	Write Protect
V_{DD}	Core Power supply
V_{DDQ}	Power supply for Input/Output
V_{PP}	Optional supply voltage for Fast Program & Erase
V _{SS}	Ground
NC	Not Connected Internally



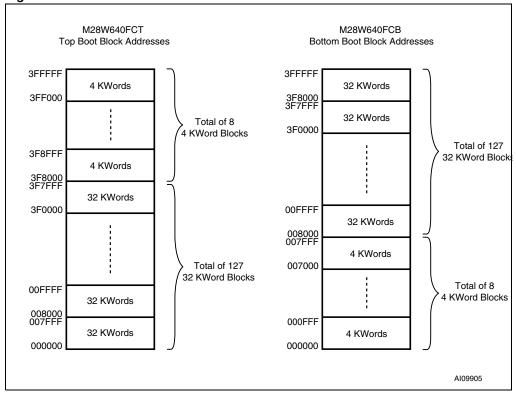


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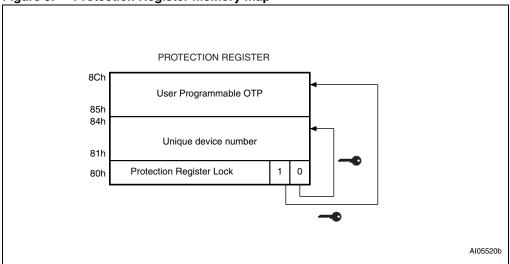
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Figure 4. Block addresses



1. Also see Appendix A, Tables 24 and 25 for a full listing of the Block Addresses.

Figure 5. Protection Register memory map



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2 Signal descriptions

See Figure 1: Logic diagram and Table 1: Signal names, for a brief overview of the signals connected to this device.

2.1 Address inputs (A0-A21)

The Address Inputs select the cells in the memory array to access during Bus Read operations. During Bus Write operations they control the commands sent to the Command Interface of the internal state machine.

2.2 Data Input/Output (DQ0-DQ15)

The Data I/O outputs the data stored at the selected address during a Bus Read operation or inputs a command or the data to be programmed during a Write Bus operation.

2.3 Chip Enable (\overline{E})

The Chip Enable input activates the memory control logic, input buffers, decoders and sense amplifiers. When Chip Enable is at V_{IL} and Reset is at V_{IH} the device is in active mode. When Chip Enable is at V_{IH} the memory is deselected, the outputs are high impedance and the power consumption is reduced to the stand-by level.

2.4 Output Enable (G)

The Output Enable controls data outputs during the Bus Read operation of the memory.

2.5 Write Enable (\overline{W})

The Write Enable controls the Bus Write operation of the memory's Command Interface. The data and address inputs are latched on the rising edge of Chip Enable, \overline{E} , or Write Enable, \overline{W} , whichever occurs first.

2.6 Write Protect (\overline{WP})

Write Protect is an input that gives an additional hardware protection for each block. When Write Protect is at V_{IL} , the Lock-Down is enabled and the protection status of the block cannot be changed. When Write Protect is at V_{IH} , the Lock-Down is disabled and the block can be locked or unlocked. (refer to *Table 7: Read Protection Register and Lock Register*).

2.7 Reset (RP)

The Reset input provides a hardware reset of the memory. When Reset is at V_{IL} , the memory is in reset mode: the outputs are high impedance and the current consumption is minimized. After Reset all blocks are in the Locked state. When Reset is at V_{IH} , the device is in normal operation. Exiting reset mode the device enters read array mode, but a negative transition of Chip Enable or a change of the address is required to ensure valid data outputs.

2.8 V_{DD} supply voltage

V_{DD} provides the power supply to the internal core of the memory device. It is the main power supply for all operations (Read, Program and Erase).

2.9 V_{DDQ} supply voltage

 V_{DDQ} provides the power supply to the I/O pins and enables all Outputs to be powered independently from V_{DD} . V_{DDQ} can be tied to V_{DD} or can use a separate supply.

2.10 V_{PP} Program supply voltage

 V_{PP} is both a control input and a power supply pin. The two functions are selected by the voltage range applied to the pin. The Supply Voltage V_{DD} and the Program Supply Voltage V_{PP} can be applied in any order.

If V_{PP} is kept in a low voltage range (0V to 3.6V) V_{PP} is seen as a control input. In this case a voltage lower than V_{PPLK} gives an absolute protection against program or erase, while $V_{PP} > V_{PP1}$ enables these functions (see *Table 15: DC characteristics*, for the relevant values). V_{PP} is only sampled at the beginning of a program or erase; a change in its value after the operation has started does not have any effect on Program or Erase, however for Double or Quadruple Word Program the results are uncertain.

If V_{PP} is in the range 11.4V to 12.6V it acts as a power supply pin. In this condition V_{PP} must be stable until the Program/Erase algorithm is completed (see *Table 17* and *Table 18*).

2.11 V_{SS} Ground

V_{SS} is the reference for all voltage measurements.

Note: Each device in a system should have V_{DD} , V_{DDQ} and V_{PP} decoupled with a $0.1\mu F$ capacitor close to the pin. See *Figure 7: AC measurement load circuit*. The PCB track widths should be sufficient to carry the required V_{PP} program and erase currents.

3 Bus operations

There are six standard bus operations that control the device. These are Bus Read, Bus Write, Output Disable, Standby, Automatic Standby and Reset. See *Table 2: Bus operations*, for a summary.

Typically glitches of less than 5ns on Chip Enable or Write Enable are ignored by the memory and do not affect bus operations.

3.1 Read

Read Bus operations are used to output the contents of the Memory Array, the Electronic Signature, the Status Register and the Common Flash Interface. Both Chip Enable and Output Enable must be at V_{IL} in order to perform a read operation. The Chip Enable input should be used to enable the device. Output Enable should be used to gate data onto the output. The data read depends on the previous command written to the memory (see Command Interface section). See *Figure 8: Read AC waveforms*, and *Table 16: Read AC characteristics*, for details of when the output becomes valid.

Read mode is the default state of the device when exiting Reset or after power-up.

3.2 Write

Bus Write operations write Commands to the memory or latch Input Data to be programmed. A write operation is initiated when Chip Enable and Write Enable are at $V_{\rm IL}$ with Output Enable at $V_{\rm IH}$. Commands, Input Data and Addresses are latched on the rising edge of Write Enable or Chip Enable, whichever occurs first.

See *Figure 9* and *Figure 10*, Write AC Waveforms, and *Table 17* and *Table 18*, Write AC Characteristics, for details of the timing requirements.

3.3 Output Disable

The data outputs are high impedance when the Output Enable is at V_{IH}.

3.4 Standby

Standby disables most of the internal circuitry allowing a substantial reduction of the current consumption. The memory is in stand-by when Chip Enable is at V_{IH} and the device is in read mode. The power consumption is reduced to the stand-by level and the outputs are set to high impedance, independently from the Output Enable or Write Enable inputs. If Chip Enable switches to V_{IH} during a program or erase operation, the device enters Standby mode when finished.

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3.5 Automatic Standby

Automatic Standby provides a low power consumption state during Read mode. Following a read operation, the device enters Automatic Standby after 150ns of bus inactivity even if Chip Enable is Low, $V_{\rm IL}$, and the supply current is reduced to $I_{\rm DD1}$. The data Inputs/Outputs will still output data if a bus Read operation is in progress.

3.6 Reset

During Reset mode when Output Enable is Low, V_{IL} , the memory is deselected and the outputs are high impedance. The memory is in Reset mode when Reset is at V_{IL} . The power consumption is reduced to the Standby level, independently from the Chip Enable, Output Enable or Write Enable inputs. If Reset is pulled to V_{SS} during a Program or Erase, this operation is aborted and the memory content is no longer valid.

Table 2. Bus operations⁽¹⁾

Operation	Ē	G	w	RP	WP	V _{PP}	DQ0-DQ15
Bus Read	V_{IL}	V _{IL}	V _{IH}	V _{IH}	Х	Don't Care	Data Output
Bus Write	V_{IL}	V _{IH}	V_{IL}	V _{IH}	Х	V _{DD} or V _{PPH}	Data Input
Output Disable	V _{IL}	V _{IH}	V _{IH}	V _{IH}	Х	Don't Care	Hi-Z
Standby	V _{IH}	Х	Х	V _{IH}	Х	Don't Care	Hi-Z
Reset	Х	Х	Х	V _{IL}	Х	Don't Care	Hi-Z

^{1.} $X = V_{IL}$ or V_{IH} , $V_{PPH} = 12V \pm 5\%$

4 Command interface

All Bus Write operations to the memory are interpreted by the Command Interface. Commands consist of one or more sequential Bus Write operations. An internal Program/Erase Controller handles all timings and verifies the correct execution of the Program and Erase commands. The Program/Erase Controller provides a Status Register whose output may be read at any time during, to monitor the progress of the operation, or the Program/Erase states. See *Table 3: Command codes*, for a summary of the commands and see *Appendix D*, *Table 32: Write State machine Current/Next*, for a summary of the Command Interface.

The Command Interface is reset to Read mode when power is first applied, when exiting from Reset or whenever V_{DD} is lower than V_{LKO} . Command sequences must be followed exactly. Any invalid combination of commands will reset the device to Read mode. Refer to *Table 4: Commands*, in conjunction with the text descriptions below.

4.1 Read Memory Array command

The Read command returns the memory to its Read mode. One Bus Write cycle is required to issue the Read Memory Array command and return the memory to Read mode. Subsequent read operations will read the addressed location and output the data. When a device Reset occurs, the memory defaults to Read mode.

4.2 Read Status Register command

The Status Register indicates when a program or erase operation is complete and the success or failure of the operation itself. Issue a Read Status Register command to read the Status Register's contents. Subsequent Bus Read operations read the Status Register at any address, until another command is issued. See *Table 11: Status Register bits*, for details on the definitions of the bits.

The Read Status Register command may be issued at any time, even during a Program/Erase operation. Any Read attempt during a Program/Erase operation will automatically output the content of the Status Register.

4.3 Read electronic signature command

The Read Electronic Signature command reads the Manufacturer and Device Codes and the Block Locking Status, or the Protection Register.

The Read Electronic Signature command consists of one write cycle, a subsequent read will output the Manufacturer Code, the Device Code, the Block Lock and Lock-Down Status, or the Protection and Lock Register. See Tables 5, 6 and 7 for the valid address.

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Table 3. Command codes

Hex Code	Command
01h	Block Lock confirm
10h	Program
20h	Erase
2Fh	Block Lock-Down confirm
30h	Double Word Program
40h	Program
50h	Clear Status Register
56h	Quadruple Word Program
60h	Block Lock, Block Unlock, Block Lock-Down
70h	Read Status Register
90h	Read Electronic Signature
98h	Read CFI Query
B0h	Program/Erase Suspend
C0h	Protection Register Program
D0h	Program/Erase Resume, Block Unlock confirm
FFh	Read Memory Array

4.4 Read CFI Query command

The Read Query Command is used to read data from the Common Flash Interface (CFI) Memory Area, allowing programming equipment or applications to automatically match their interface to the characteristics of the device. One Bus Write cycle is required to issue the Read Query Command. Once the command is issued subsequent Bus Read operations read from the Common Flash Interface Memory Area. See *Appendix B: Common Flash Interface (CFI)*, Tables *26*, *27*, *28*, *29*, *30* and *31* for details on the information contained in the Common Flash Interface memory area.

4.5 Block Erase command

The Block Erase command can be used to erase a block. It sets all the bits within the selected block to '1'. All previous data in the block is lost. If the block is protected then the Erase operation will abort, the data in the block will not be changed and the Status Register will output the error.

Two Bus Write cycles are required to issue the command.

- The first bus cycle sets up the Erase command.
- The second latches the block address in the internal state machine and starts the Program/Erase Controller.

If the second bus cycle is not Write Erase Confirm (D0h), Status Register bits b4 and b5 are set and the command aborts.

Erase aborts if Reset turns to V_{IL} . As data integrity cannot be guaranteed when the Erase operation is aborted, the block must be erased again.

During Erase operations the memory will accept the Read Status Register command and the Program/Erase Suspend command, all other commands will be ignored. Typical Erase times are given in *Table 8: Program, Erase Times and Program/Erase endurance cycles*.

See *Appendix C*, *Figure 20: Erase flowchart and pseudo code*, for a suggested flowchart for using the Erase command.

4.6 Program command

The memory array can be programmed word-by-word. Two bus write cycles are required to issue the Program Command.

- The first bus cycle sets up the Program command.
- The second latches the Address and the Data to be written and starts the Program/Erase Controller.

During Program operations the memory will accept the Read Status Register command and the Program/Erase Suspend command. Typical Program times are given in *Table 8: Program, Erase Times and Program/Erase endurance cycles.*

Programming aborts if Reset goes to V_{IL} . As data integrity cannot be guaranteed when the program operation is aborted, the block containing the memory location must be erased and reprogrammed.

See *Appendix C*, *Figure 16: Program flowchart and pseudo code*, for the flowchart for using the Program command.

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4.7 Double Word Program command

This feature is offered to improve the programming throughput, writing a page of two adjacent words in parallel. The two words must differ only for the address A0. Programming should not be attempted when V_{PP} is not at V_{PPH} .

Three bus write cycles are necessary to issue the Double Word Program command.

- The first bus cycle sets up the Double Word Program Command.
- The second bus cycle latches the Address and the Data of the first word to be written.
- The third bus cycle latches the Address and the Data of the second word to be written and starts the Program/Erase Controller.

Read operations output the Status Register content after the programming has started. Programming aborts if Reset goes to V_{IL} . As data integrity cannot be guaranteed when the program operation is aborted, the block containing the memory location must be erased and reprogrammed.

See *Appendix C*, *Figure 17: Double Word Program flowchart and pseudo code* for the flowchart for using the Double Word Program command.

4.8 Quadruple Word Program command

This feature is offered to improve the programming throughput, writing a page of four adjacent words in parallel. The four words must differ only for the addresses A0 and A1. Programming should not be attempted when V_{PP} is not at V_{PPH}.

Five bus write cycles are necessary to issue the Quadruple Word Program command.

- The first bus cycle sets up the Quadruple Word Program Command.
- The second bus cycle latches the Address and the Data of the first word to be written.
- The third bus cycle latches the Address and the Data of the second word to be written.
- The fourth bus cycle latches the Address and the Data of the third word to be written.
- The fifth bus cycle latches the Address and the Data of the fourth word to be written and starts the Program/Erase Controller.

Read operations output the Status Register content after the programming has started. Programming aborts if Reset goes to V_{IL} . As data integrity cannot be guaranteed when the program operation is aborted, the block containing the memory location must be erased and reprogrammed.

See *Appendix C*, *Figure 18: Quadruple Word Program flowchart and pseudo code*, for the flowchart for using the Quadruple Word Program command.

4.9 Clear Status Register command

The Clear Status Register command can be used to reset bits 1, 3, 4 and 5 in the Status Register to '0'. One bus write cycle is required to issue the Clear Status Register command.

The bits in the Status Register do not automatically return to '0' when a new Program or Erase command is issued. The error bits in the Status Register should be cleared before attempting a new Program or Erase command.

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4.10 Program/Erase Suspend command

The Program/Erase Suspend command is used to pause a Program or Erase operation. One bus write cycle is required to issue the Program/Erase command and pause the Program/Erase controller.

During Program/Erase Suspend the Command Interface will accept the Program/Erase Resume, Read Array, Read Status Register, Read Electronic Signature and Read CFI Query commands. Additionally, if the suspend operation was Erase then the Program, Double Word Program, Quadruple Word Program, Block Lock, Block Lock-Down or Protection Program commands will also be accepted. The block being erased may be protected by issuing the Block Protect, Block Lock or Protection Program commands. When the Program/Erase Resume command is issued the operation will complete. Only the blocks not being erased may be read or programmed correctly.

During a Program/Erase Suspend, the device can be placed in a pseudo-standby mode by taking Chip Enable to V_{IH} . Program/Erase is aborted if Reset turns to V_{II} .

See Appendix C, Figure 19: Program Suspend & Resume flowchart and pseudo code, and Figure 21: Erase Suspend & Resume flowchart and pseudo code, for flowcharts for using the Program/Erase Suspend command.

4.11 Program/Erase Resume command

The Program/Erase Resume command can be used to restart the Program/Erase Controller after a Program/Erase Suspend operation has paused it. One Bus Write cycle is required to issue the command. Once the command is issued subsequent Bus Read operations read the Status Register.

See Appendix C, Figure 19: Program Suspend & Resume flowchart and pseudo code, and Figure 21: Erase Suspend & Resume flowchart and pseudo code, for flowcharts for using the Program/Erase Resume command.

4.12 Protection Register Program command

The Protection Register Program command is used to Program the 128 bit user One-Time-Programmable (OTP) segment of the Protection Register. The segment is programmed 16 bits at a time. When shipped all bits in the segment are set to '1'. The user can only program the bits to '0'.

Two write cycles are required to issue the Protection Register Program command.

- The first bus cycle sets up the Protection Register Program command.
- The second latches the Address and the Data to be written to the Protection Register and starts the Program/Erase Controller.

Read operations output the Status Register content after the programming has started.

The segment can be protected by programming bit 1 of the Protection Lock Register (see *Figure 5: Protection Register memory map*). Attempting to program a previously protected Protection Register will result in a Status Register error. The protection of the Protection Register is not reversible.

The Protection Register Program cannot be suspended.

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4.13 Block Lock command

The Block Lock command is used to lock a block and prevent Program or Erase operations from changing the data in it. All blocks are locked at power-up or reset.

Two Bus Write cycles are required to issue the Block Lock command.

- The first bus cycle sets up the Block Lock command.
- The second Bus Write cycle latches the block address.

The lock status can be monitored for each block using the Read Electronic Signature command. *Table 10* shows the protection status after issuing a Block Lock command.

The Block Lock bits are volatile, once set they remain set until a hardware reset or power-down/power-up. They are cleared by a Blocks Unlock command. Refer to the section, Block Locking, for a detailed explanation.

4.14 Block Unlock command

The Block Unlock command is used to unlock a block, allowing the block to be programmed or erased. Two Bus Write cycles are required to issue the Block Unlock command.

- The first bus cycle sets up the Block Unlock command.
- The second Bus Write cycle latches the block address.

The lock status can be monitored for each block using the Read Electronic Signature command. *Table 10* shows the protection status after issuing a Block Unlock command. Refer to the section, Block Locking, for a detailed explanation.

4.15 Block Lock-Down command

A locked block cannot be Programmed or Erased, or have its protection status changed when \overline{WP} is low, V_{IL} . When \overline{WP} is high, $V_{IH,}$ the Lock-Down function is disabled and the locked blocks can be individually unlocked by the Block Unlock command.

Two Bus Write cycles are required to issue the Block Lock-Down command.

- The first bus cycle sets up the Block Lock command.
- The second Bus Write cycle latches the block address.

The lock status can be monitored for each block using the Read Electronic Signature command. Locked-Down blocks revert to the locked (and not locked-down) state when the device is reset on power-down. *Table 10* shows the protection status after issuing a Block Lock-Down command. Refer to the section, Block Locking, for a detailed explanation.

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Table 4. Commands⁽¹⁾

	Cycles		Bus Write operations													
Commands		1:	st Cyc	ele	2nd Cycle			3rd Cycle			4th Cycle			5th Cycle		
	၁	Op.	Add	Data	Op.	Add	Data	Op.	Add	Data	Op.	Add	Data	Op.	Add	Data
Read Memory Array	1+	Write	х	FFh	Read	RA	RD									
Read Status Register	1+	Write	Х	70h	Read	Х	SRD									
Read Electronic Signature	1+	Write	х	90h	Read	SA ⁽²⁾	IDh									
Read CFI Query	1+	Write	Х	98h	Read	QA	QD									
Erase	2	Write	Х	20h	Write	ВА	D0h									
Program	2	Write	Х	40h or 10h	Write	PA	PD									
Double Word Program ⁽³⁾	3	Write	Х	30h	Write	PA1	PD1	Write	PA2	PD2						
Quadruple Word Program ⁽⁴⁾	5	Write	х	56h	Write	PA1	PD1	Write	PA2	PD2	Write	PA3	PD3	Write	PA4	PD4
Clear Status Register	1	Write	Х	50h												
Program/Erase Suspend	1	Write	Х	B0h												
Program/Erase Resume	1	Write	Х	D0h												
Block Lock	2	Write	Х	60h	Write	ВА	01h									
Block Unlock	2	Write	Х	60h	Write	ВА	D0h									
Block Lock- Down	2	Write	Х	60h	Write	ВА	2Fh									
Protection Register Program	2	Write	х	C0h	Write	PRA	PRD									

X = Don't Care,RA=Read Address,RD=Read Data, SRD=Status Register Data, ID=Identifier (Manufacture and Device Code), QA=Query Address, QD=Query Data, BA=Block Address, PA=Program Address, PD=Program Data, PRA=Protection Register Address, PRD=Protection Register Data.

^{2.} The signature addresses are listed in Tables $\it 5$, $\it 6$ and $\it 7$.

^{3.} Program Addresses 1 and 2 must be consecutive Addresses differing only for A0.

^{4.} Program Addresses 1,2,3 and 4 must be consecutive Addresses differing only for A0 and A1.

Table 5. Read Electronic signature⁽¹⁾

Code	Device	Ē	G	w	Α0	A 1	A2-A7	A8-A21	DQ0-DQ7	DQ8- DQ15
Manufacture Code		V_{IL}	V_{IL}	V _{IH}	V_{IL}	V _{IL}	0	Don't Care	20h	00h
Device Code	M28W640 FCT	V_{IL}	V_{IL}	V_{IH}	V_{IH}	V_{IL}	0	Don't Care	48h	88h
	M28W640 FCB	V_{IL}	V _{IL}	V _{IH}	V _{IH}	V _{IL}	0	Don't Care	49h	88h

^{1.} $\overline{RP} = V_{IH}$.

Table 6. Read Block Lock signature

Block Status	Ē	G	w	Α0	A 1	A2-A7	A8-A11	A12-A21	DQ0	DQ1	DQ2- DQ15
Locked Block	V _{IL}	V _{IL}	V _{IH}	V _{IL}	V_{IH}	0	Don't Care	Block Address	1	0	00h
Unlocked Block	V _{IL}	V _{IL}	V _{IH}	V _{IL}	V_{IH}	0	Don't Care	Block Address	0	0	00h
Locked- Down Block	V _{IL}	V _{IL}	V _{IH}	V _{IL}	V_{IH}	0	Don't Care	Block Address	X ⁽¹⁾	1	00h

^{1.} A Locked-Down Block can be locked "DQ0 = 1" or unlocked "DQ0 = 0"; see Block Locking section.

Table 7. Read Protection Register and Lock Register

Word	Ē	G	W	A0-A7	A8-A21	DQ0	DQ1	DQ2	DQ3-	DQ8-
									DQ7	DQ15
Lock	V _{IL}	V _{IL}	V _{IH}	80h	Don't Care	0	OTP Prot. data	0	00h	00h
Unique ID 0	V _{IL}	V _{IL}	V _{IH}	81h	Don't Care	ID data	ID data	ID data	ID data	ID data
Unique ID 1	V _{IL}	V _{IL}	V _{IH}	82h	Don't Care	ID data	ID data	ID data	ID data	ID data
Unique ID 2	V _{IL}	V _{IL}	V _{IH}	83h	Don't Care	ID data	ID data	ID data	ID data	ID data
Unique ID 3	V _{IL}	V _{IL}	V _{IH}	84h	Don't Care	ID data	ID data	ID data	ID data	ID data
OTP 0	V _{IL}	V_{IL}	V _{IH}	85h	Don't Care	OTP data	OTP data	OTP data	OTP data	OTP data
OTP 1	V _{IL}	V _{IL}	V _{IH}	86h	Don't Care	OTP data	OTP data	OTP data	OTP data	OTP data
OTP 2	V _{IL}	V _{IL}	V _{IH}	87h	Don't Care	OTP data	OTP data	OTP data	OTP data	OTP data
OTP 3	V _{IL}	V_{IL}	V _{IH}	88h	Don't Care	OTP data	OTP data	OTP data	OTP data	OTP data
OTP 4	V _{IL}	V _{IL}	V _{IH}	89h	Don't Care	OTP data	OTP data	OTP data	OTP data	OTP data
OTP 5	V _{IL}	V _{IL}	V _{IH}	8Ah	Don't Care	OTP data	OTP data	OTP data	OTP data	OTP data
OTP 6	V _{IL}	V _{IL}	V _{IH}	8Bh	Don't Care	OTP data	OTP data	OTP data	OTP data	OTP data
OTP 7	V _{IL}	V _{IL}	V _{IH}	8Ch	Don't Care	OTP data	OTP data	OTP data	OTP data	OTP data

Table 8. Program, Erase Times and Program/Erase endurance cycles

Parameter	Test Conditions	M28W64	Unit			
Farameter	rest Conditions	Min	Тур	Max	Ollit	
Word Program	$V_{PP} = V_{DD}$		10	200	μs	
Double Word Program	V _{PP} = 12V ±5%		10	200	μs	
Quadruple Word Program	V _{PP} = 12V ±5%		10	200	μs	
Main Block Drogram	V _{PP} = 12V ±5%		0.16/0.08 (1)	5	S	
Main Block Program	$V_{PP} = V_{DD}$		0.32	5	S	
Parameter Plack Program	V _{PP} = 12V ±5%		0.02/0.01 (1)	4	S	
Parameter Block Program	$V_{PP} = V_{DD}$		0.04	4	S	
Main Block Erase	V _{PP} = 12V ±5%		1	10	S	
Wall block Elase	$V_{PP} = V_{DD}$		1	10	S	
Doromotor Block Eroco	V _{PP} = 12V ±5%		0.4	10	S	
Parameter Block Erase	$V_{PP} = V_{DD}$		0.4	10	S	
Program/Erase Cycles (per Block)		100,000			cycles	

Typical time to program a Main or Parameter Block using the Double Word Program and the Quadruple Word Program commands respectively.

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5 Block locking

The M28W640FCT and M28W640FCB feature an instant, individual block locking scheme that allows any block to be locked or unlocked with no latency. This locking scheme has three levels of protection.

- Lock/Unlock this first level allows software-only control of block locking.
- Lock-Down this second level requires hardware interaction before locking can be changed.
- V_{PP} ≤V_{PPLK} the third level offers a complete hardware protection against program and erase on all blocks.

The protection status of each block can be set to Locked, Unlocked, and Lock-Down. *Table 10*, defines all of the possible protection states (WP, DQ1, DQ0), and *Appendix C*, *Figure 22*, shows a flowchart for the locking operations.

5.1 Reading a Block's Lock status

The lock status of every block can be read in the Read Electronic Signature mode of the device. To enter this mode write 90h to the device. Subsequent reads at the address specified in *Table 6*, will output the protection status of that block. The lock status is represented by DQ0 and DQ1. DQ0 indicates the Block Lock/Unlock status and is set by the Lock command and cleared by the Unlock command. It is also automatically set when entering Lock-Down. DQ1 indicates the Lock-Down status and is set by the Lock-Down command. It cannot be cleared by software, only by a hardware reset or power-down.

The following sections explain the operation of the locking system.

5.2 Locked state

The default status of all blocks on power-up or after a hardware reset is Locked (states (0,0,1) or (1,0,1)). Locked blocks are fully protected from any program or erase. Any program or erase operations attempted on a locked block will return an error in the Status Register. The Status of a Locked block can be changed to Unlocked or Lock-Down using the appropriate software commands. An Unlocked block can be Locked by issuing the Lock command.

5.3 Unlocked state

Unlocked blocks (states (0,0,0), (1,0,0) (1,1,0)), can be programmed or erased. All unlocked blocks return to the Locked state after a hardware reset or when the device is powered-down. The status of an unlocked block can be changed to Locked or Locked-Down using the appropriate software commands. A locked block can be unlocked by issuing the Unlock command.

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5.4 Lock-Down state

Blocks that are Locked-Down (state (0,1,x))are protected from program and erase operations (as for Locked blocks) but their protection status cannot be changed using software commands alone. A Locked or Unlocked block can be Locked-Down by issuing the Lock-Down command. Locked-Down blocks revert to the Locked state when the device is reset or powered-down.

The Lock-Down function is dependent on the \overline{WP} input pin. When \overline{WP} =0 (V_{IL}), the blocks in the Lock-Down state (0,1,x) are protected from program, erase and protection status changes. When \overline{WP} =1 (V_{IH}) the Lock-Down function is disabled (1,1,1) and Locked-Down blocks can be individually unlocked to the (1,1,0) state by issuing the software command, where they can be erased and programmed. These blocks can then be relocked (1,1,1) and unlocked (1,1,0) as desired while \overline{WP} remains high. When \overline{WP} is low , blocks that were previously Locked-Down return to the Lock-Down state (0,1,x) regardless of any changes made while \overline{WP} was high. Device reset or power-down resets all blocks , including those in Lock-Down, to the Locked state.

5.5 Locking Operations during Erase Suspend

Changes to block lock status can be performed during an erase suspend by using the standard locking command sequences to unlock, lock or lock-down a block. This is useful in the case when another block needs to be updated while an erase operation is in progress.

To change block locking during an erase operation, first write the Erase Suspend command, then check the status register until it indicates that the erase operation has been suspended. Next write the desired Lock command sequence to a block and the lock status will be changed. After completing any desired lock, read, or program operations, resume the erase operation with the Erase Resume command.

If a block is locked or locked-down during an erase suspend of the same block, the locking status bits will be changed immediately, but when the erase is resumed, the erase operation will complete.

Locking operations cannot be performed during a program suspend. Refer to *Appendix D*, Command Interface and Program/Erase Controller State, for detailed information on which commands are valid during erase suspend.

Table 9. Block Lock status

Item	Address	Data
Block Lock Configuration		LOCK
Block is Unlocked	xx002	DQ0=0
Block is Locked	***************************************	DQ0=1
Block is Locked-Down		DQ1=1

Table 10. Protection status

	ection Status ⁽¹⁾ Q1, DQ0)			ection Status ⁽¹⁾ DQ1, DQ0)	
Current State	Program/Erase Allowed	After Block Lock Command	After Block Unlock Command	After Block Lock-Down Command	After WP transition
1,0,0	yes	1,0,1	1,0,0	1,1,1	0,0,0
1,0,1 ⁽²⁾	no	1,0,1	1,0,0	1,1,1	0,0,1
1,1,0	yes	1,1,1	1,1,0	1,1,1	0,1,1
1,1,1	no	1,1,1	1,1,0	1,1,1	0,1,1
0,0,0	yes	0,0,1	0,0,0	0,1,1	1,0,0
0,0,1 ⁽²⁾	no	0,0,1	0,0,0	0,1,1	1,0,1
0,1,1	no	0,1,1	0,1,1	0,1,1	1,1,1 or 1,1,0 ⁽³⁾

The lock status is defined by the write protect pin and by DQ1 ('1' for a locked-down block) and DQ0 ('1' for a locked block) as read in the Read Electronic Signature command with A1 = V_{IH} and A0 = V_{IL}.

^{2.} All blocks are locked at power-up, so the default configuration is 001 or 101 according to $\overline{\text{WP}}$ status.

^{3.} A $\overline{\text{WP}}$ transition to V_{IH} on a locked block will restore the previous DQ0 value, giving a 111 or 110.

6 Status Register

The Status Register provides information on the current or previous Program or Erase operation. The various bits convey information and errors on the operation. To read the Status register the Read Status Register command can be issued, refer to Read Status Register Command section. To output the contents, the Status Register is latched on the falling edge of the Chip Enable or Output Enable signals, and can be read until Chip Enable or Output Enable returns to V_{IH} . Either Chip Enable or Output Enable must be toggled to update the latched data.

Bus Read operations from any address always read the Status Register during Program and Erase operations.

The bits in the Status Register are summarized in *Table 11: Status Register bits*. Refer to *Table 11* in conjunction with the following text descriptions.

6.1 Program/Erase Controller status (bit 7)

The Program/Erase Controller Status bit indicates whether the Program/Erase Controller is active or inactive. When the Program/Erase Controller Status bit is Low (set to '0'), the Program/Erase Controller is active; when the bit is High (set to '1'), the Program/Erase Controller is inactive, and the device is ready to process a new command.

The Program/Erase Controller Status is Low immediately after a Program/Erase Suspend command is issued until the Program/Erase Controller pauses. After the Program/Erase Controller pauses the bit is High.

During Program, Erase, operations the Program/Erase Controller Status bit can be polled to find the end of the operation. Other bits in the Status Register should not be tested until the Program/Erase Controller completes the operation and the bit is High.

After the Program/Erase Controller completes its operation the Erase Status, Program Status, V_{PP} Status and Block Lock Status bits should be tested for errors.

6.2 Erase Suspend status (bit 6)

The Erase Suspend Status bit indicates that an Erase operation has been suspended or is going to be suspended. When the Erase Suspend Status bit is High (set to '1'), a Program/Erase Suspend command has been issued and the memory is waiting for a Program/Erase Resume command.

The Erase Suspend Status should only be considered valid when the Program/Erase Controller Status bit is High (Program/Erase Controller inactive). Bit 7 is set within 30µs of the Program/Erase Suspend command being issued therefore the memory may still complete the operation rather than entering the Suspend mode.

When a Program/Erase Resume command is issued the Erase Suspend Status bit returns Low.

6.3 Erase status (bit 5)

The Erase Status bit can be used to identify if the memory has failed to verify that the block has erased correctly. When the Erase Status bit is High (set to '1'), the Program/Erase Controller has applied the maximum number of pulses to the block and still failed to verify that the block has erased correctly. The Erase Status bit should be read once the Program/Erase Controller Status bit is High (Program/Erase Controller inactive).

Once set High, the Erase Status bit can only be reset Low by a Clear Status Register command or a hardware reset. If set High it should be reset before a new Program or Erase command is issued, otherwise the new command will appear to fail.

6.4 Program status (bit 4)

The Program Status bit is used to identify a Program failure. When the Program Status bit is High (set to '1'), the Program/Erase Controller has applied the maximum number of pulses to the byte and still failed to verify that it has programmed correctly. The Program Status bit should be read once the Program/Erase Controller Status bit is High (Program/Erase Controller inactive).

Once set High, the Program Status bit can only be reset Low by a Clear Status Register command or a hardware reset. If set High it should be reset before a new command is issued, otherwise the new command will appear to fail.

6.5 V_{PP} status (bit 3)

The V_{PP} Status bit can be used to identify an invalid voltage on the V_{PP} pin during Program and Erase operations. The V_{PP} pin is only sampled at the beginning of a Program or Erase operation. Indeterminate results can occur if V_{PP} becomes invalid during an operation.

When the V_{PP} Status bit is Low (set to '0'), the voltage on the V_{PP} pin was sampled at a valid voltage; when the V_{PP} Status bit is High (set to '1'), the V_{PP} pin has a voltage that is below the V_{PP} Lockout Voltage, V_{PPLK} , the memory is protected and Program and Erase operations cannot be performed.

Once set High, the V_{PP} Status bit can only be reset Low by a Clear Status Register command or a hardware reset. If set High it should be reset before a new Program or Erase command is issued, otherwise the new command will appear to fail.

6.6 Program Suspend status (bit 2)

The Program Suspend Status bit indicates that a Program operation has been suspended. When the Program Suspend Status bit is High (set to '1'), a Program/Erase Suspend command has been issued and the memory is waiting for a Program/Erase Resume command. The Program Suspend Status should only be considered valid when the Program/Erase Controller Status bit is High (Program/Erase Controller inactive). Bit 2 is set within 5µs of the Program/Erase Suspend command being issued therefore the memory may still complete the operation rather than entering the Suspend mode.

When a Program/Erase Resume command is issued the Program Suspend Status bit returns Low.

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6.7 Block Protection status (bit 1)

The Block Protection Status bit can be used to identify if a Program or Erase operation has tried to modify the contents of a locked block.

When the Block Protection Status bit is High (set to '1'), a Program or Erase operation has been attempted on a locked block.

Once set High, the Block Protection Status bit can only be reset Low by a Clear Status Register command or a hardware reset. If set High it should be reset before a new command is issued, otherwise the new command will appear to fail.

6.8 Reserved (bit 0)

Bit 0 of the Status Register is reserved. Its value must be masked.

Note: Refer to Appendix C: Flowcharts and pseudo codes, for using the Status Register.

Table 11. Status Register bits⁽¹⁾

Bit	Name	Logic Level	Definition	
7	P/E.C. Status	'1'	Ready	
/	P/E.C. Status	'0'	Busy	
6	Eroop Cuanand Status	'1'	Suspended	
6	Erase Suspend Status	'0'	In progress or Completed	
5	Erase Status	'1'	Erase Error	
5	Erase Status	'0'		
4	Due suce on Chatus	'1'	Program Error	
4	Program Status	'0'	Program Success	
3	V Ctatus	'1'	V _{PP} Invalid, Abort	
3	V _{PP} Status	'0'	V _{PP} OK	
2	Drogram Cuanand Status	'1'	Suspended	
2	Program Suspend Status	'0'	In Progress or Completed	
1	Block Protection Status	'1'	Program/Erase on protected Block, Abort	
		'0'	No operation to protected blocks	
0	Reserved			

^{1.} Logic level '1' is High, '0' is Low.

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7 Maximum rating

Stressing the device above the rating listed in the Absolute Maximum Ratings table may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the Operating sections of this specification is not implied. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability. Refer also to the Numonyx SURE Program and other relevant quality documents.

Table 12. Absolute maximum ratings

Symbol	Parameter	Valu	Unit	
Symbol	rai ailletei	Min	Max	Oille
T _A	Ambient Operating Temperature (1)	- 40	85	°C
T _{BIAS}	Temperature Under Bias	- 40	125	°C
T _{STG}	Storage Temperature	– 55	155	°C
V _{IO}	Input or Output voltage	- 0.6	V _{DDQ} +0.6	V
V_{DD} , V_{DDQ}	Supply voltage	- 0.6	4.1	V
V _{PP}	Program voltage	- 0.6	13	V

^{1.} Depends on range.

8 DC and AC parameters

This section summarizes the operating and measurement conditions, and the DC and AC characteristics of the device. The parameters in the DC and AC characteristics Tables that follow, are derived from tests performed under the Measurement Conditions summarized in *Table 13: Operating and AC measurement conditions*. Designers should check that the operating conditions in their circuit match the measurement conditions when relying on the quoted parameters.

Table 13. Operating and AC measurement conditions

		M28W640FCT, M28W640FCB							
Parameter	7	0	85		90		10		l lee!te
	Min	Max	Min	Max	Min	Max	Min	Max	Units
V _{DD} supply voltage	2.7	3.6	2.7	3.6	2.7	3.6	2.7	3.6	V
V_{DDQ} supply voltage $(V_{DDQ} \le V_{DD})$	2.7	3.6	2.7	3.6	2.7	3.6	1.65	3.6	V
Ambient Operating Temperature	-40	85	-40	85	-40	85	-40	85	°C
Load capacitance (C _L)	50		50		50		50		pF
Input Rise and Fall Times		5		5		5		5	ns
Input pulse voltages	0 to V _{DDQ}		0 to V _{DDQ}		0 to V _{DDQ}		0 to V _{DDQ}		V
Input and Output Timing Ref. voltages	V _{DE}	_{OQ} /2	V _{DE}	_{0Q} /2	V _{DDQ} /2		V _{DDQ} /2		V

Figure 6. AC measurement I/O waveform

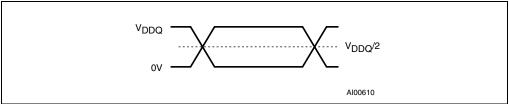


Figure 7. AC measurement load circuit

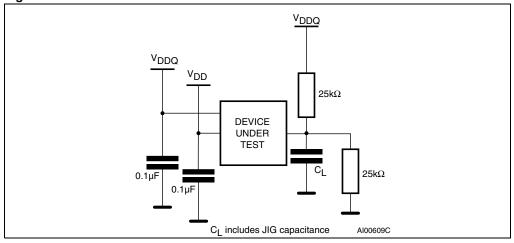


Table 14. Capacitance⁽¹⁾

Symbol	Parameter	Test Condition	Min	Max	Unit
C _{IN}	Input capacitance	$V_{IN} = 0V$		6	pF
C _{OUT}	Output capacitance	V _{OUT} = 0V		12	pF

^{1.} Sampled only, not 100% tested.

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Table 15. DC characteristics

Symbol	Parameter	Test condition	Min	Тур	Max	Unit
ILI	Input Leakage Current	0V≤V _{IN} ≤V _{DDQ}			±1	μΑ
I _{LO}	Output Leakage Current	0V≤V _{OUT} ≰V _{DDQ}			±10	μΑ
I _{DD}	Supply Current (Read)	$\overline{E} = V_{SS}, \overline{G} = V_{IH},$ $f = 5MHz$		9	18	mA
I _{DD1}	Supply Current (Stand-by or Automatic Stand-by)	$\overline{E} = V_{DDQ} \pm 0.2V,$ $\overline{RP} = V_{DDQ} \pm 0.2V$		15	50	μΑ
I _{DD2}	Supply Current (Reset)	$\overline{RP} = V_{SS} \pm 0.2V$		15	50	μΑ
I _{DD3}	Supply Current (Program)	Program in progress $V_{PP} = 12V \pm 5\%$		5	10	mA
3003	oupply outlett (Frogram)	Program in progress V _{PP} = V _{DD}		10	20	mA
I _{DD4}	Supply Current (Erase)	Erase in progress $V_{PP} = 12V \pm 5\%$		5	20	mA
יטט4	oupply outlett (Elase)	Erase in progress $V_{PP} = V_{DD}$		10	20	mA
I _{DD5}	Supply Current (Program/Erase Suspend)	$\overline{E} = V_{DDQ} \pm 0.2V$, Erase suspended		15	50	μΑ
I _{PP}	Program Current (Read or Stand-by)	$V_{PP} > V_{DD}$			400	μΑ
I _{PP1}	Program Current (Read or Stand-by)	V _{PP} ≤V _{DD}		1	5	μΑ
I _{PP2}	Program Current (Reset)	$\overline{RP} = V_{SS} \pm 0.2V$		1	5	μΑ
lone	Program Current (Program)	Program in progress V_{PP} = 12V ± 5%		1	10	mA
I _{PP3}	Trogram current (Frogram)	Program in progress $V_{PP} = V_{DD}$		1	5	μΑ
lan.	Program Current (Erase)	Erase in progress $V_{PP} = 12V \pm 5\%$		3	10	mA
I _{PP4}	Trogram Current (Liase)	Erase in progress $V_{PP} = V_{DD}$		1	5	μΑ
V _{IL}	Input Low voltage		-0.5		0.4	V
V IL	Input Low voltage	$V_{DDQ} \ge 2.7V$	-0.5		0.8	V
V _{IH}	Input High voltage		V _{DDQ} -0.4		V _{DDQ} +0.4	V
* IH		V _{DDQ} ≥ 2.7V	0.7 V _{DDQ}		V _{DDQ} +0.4	V
V _{OL}	Output Low voltage	$\begin{split} I_{OL} &= 100 \mu A, \\ V_{DD} &= V_{DD} \text{ min,} \\ V_{DDQ} &= V_{DDQ} \text{ min} \end{split}$			0.1	V
V _{OH}	Output High voltage	$\begin{split} I_{OH} &= -100 \mu A, \\ V_{DD} &= V_{DD} min, \\ V_{DDQ} &= V_{DDQ} min \end{split}$	V _{DDQ} –0.1			V

Table 15. DC characteristics (continued)

Symbol	Parameter	Test condition	Min	Тур	Max	Unit
V _{PP1}	Program voltage (Program or Erase operations)		1.65		3.6	V
V _{PPH}	Program voltage (Program or Erase operations)		11.4		12.6	V
V _{PPLK}	Program voltage (Program and Erase lock-out)				1	V
V _{LKO}	V _{DD} supply voltage (Program and Erase lock-out)				2	V

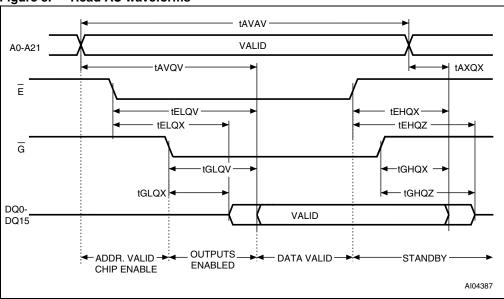


Figure 8. Read AC waveforms

Table 16. Read AC characteristics

Cumbal	Alt	Dozomotov	Parameter -		640FCT,	M28W6	40FCB	Heit
Symbol	AIL	Parameter			85	90	10	Unit
t _{AVAV}	t _{RC}	Address Valid to Next Address Valid	Min	70	85	90	100	ns
t _{AVQV}	t _{ACC}	Address Valid to Output Valid	Max	70	85	90	100	ns
t _{AXQX} (1)	t _{OH}	Address Transition to Output Transition	Min	0	0	0	0	ns
t _{EHQX} (1)	t _{OH}	Chip Enable High to Output Min		0	0	0	0	ns
t _{EHQZ} (1)	t _{HZ}	Chip Enable High to Output Hi-Z	Max	20	20	25	25	ns
t _{ELQV} (2)	t _{CE}	Chip Enable Low to Output Valid	Max	70	85	90	100	ns
t _{ELQX} (1)	t _{LZ}	Chip Enable Low to Output Transition	Min	0	0	0	0	ns
t _{GHQX}	t _{OH}	Output Enable High to Output Transition	Min	0	0	0	0	ns
t _{GHQZ} (1)	t _{DF}	Output Enable High to Output Hi-Z Max		20	20	25	25	ns
t _{GLQV} (2)	t _{OE}	Output Enable Low to Output Valid Max		20	20	30	35	ns
t _{GLQX} (1)	t _{OLZ}	Output Enable Low to Output Transition	Min	0	0	0	0	ns

^{1.} Sampled only, not 100% tested.

^{2.} \overline{G} may be delayed by up to t_{ELQV} - t_{GLQV} after the falling edge of \overline{E} without increasing t_{ELQV}

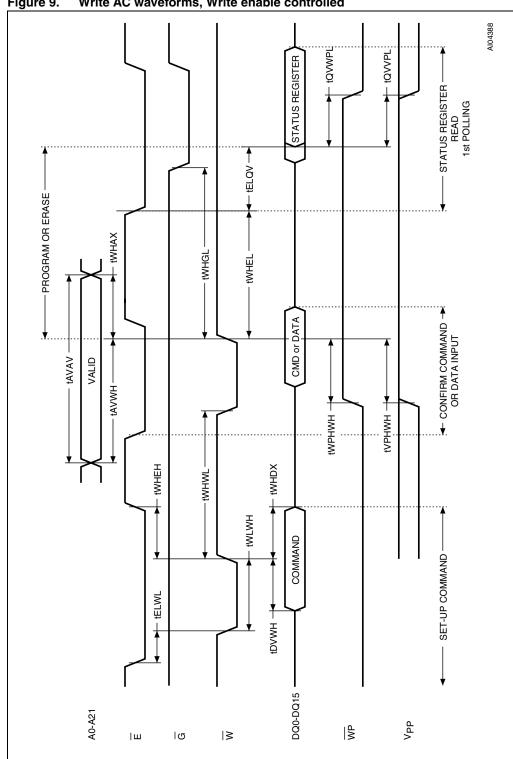


Figure 9. Write AC waveforms, Write enable controlled

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Table 17. Write AC characteristics, Write enable controlled

Symbol	Alt	Parameter			M28W6 M28W6	,		Unit
					85	90	10	
t _{AVAV}	t_{WC}	Write Cycle Time	Min	70	85	90	100	ns
t _{AVWH}	t _{AS}	Address Valid to Write Enable High	Min	45	45	50	50	ns
t _{DVWH}	t _{DS}	Data Valid to Write Enable High	Min	45	45	50	50	ns
t _{ELWL}	t _{CS}	Chip Enable Low to Write Enable Low	Min	0	0	0	0	ns
t _{ELQV}		Chip Enable Low to Output Valid	Min	70	85	90	100	ns
t _{QVVPL} (1)		Output Valid to V _{PP} Low Min		0	0	0	0	ns
t _{QVWPL}		Output Valid to Write Protect Low Min		0	0	0	0	ns
t _{VPHWH} (1)	t _{VPS}	V _{PP} High to Write Enable High Min		200	200	200	200	ns
t _{WHAX}	t _{AH}	Write Enable High to Address Transition	Min	0	0	0	0	ns
t _{WHDX}	t _{DH}	Write Enable High to Data Transition	Min	0	0	0	0	ns
t _{WHEH}	t _{CH}	Write Enable High to Chip Enable High	Min	0	0	0	0	ns
t _{WHEL}		Write Enable High to Chip Enable Low	Min	25	25	30	30	ns
twHGL		Write Enable High to Output Enable Low			20	30	30	ns
t _{WHWL}	t _{WP} H	Write Enable High to Write Enable Low		25	25	30	30	ns
t _{WLWH}	t _{WP}	Write Enable Low to Write Enable High		45	45	50	50	ns
t _{WPHWH}		Write Protect High to Write Enable High	Min	45	45	50	50	ns

^{1.} Sampled only, not 100% tested.

^{2.} Applicable if V_{PP} is seen as a logic input ($V_{PP} < 3.6V$).

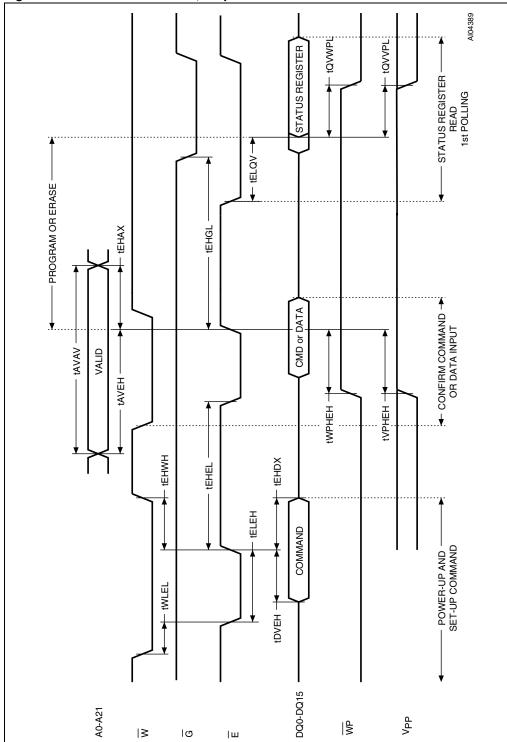


Figure 10. Write AC waveforms, Chip enable controlled

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Table 18. Write AC characteristics, Chip enable controlled

0 1 1	Sumbal All Barranata		M28W640F					
Symbol	Alt	Parameter		70	85	90	10	Unit
t _{AVAV}	t _{WC}	Write Cycle Time	Min	70	85	90	100	ns
t _{AVEH}	t _{AS}	Address Valid to Chip Enable High	Min	45	45	50	50	ns
t _{DVEH}	t _{DS}	Data Valid to Chip Enable High	Min	45	45	50	50	ns
t _{EHAX}	t _{AH}	Chip Enable High to Address Transition	Min	0	0	0	0	ns
t _{EHDX}	t _{DH}	Chip Enable High to Data Transition	Min	0	0	0	0	ns
t _{EHEL}	t _{CPH}	Chip Enable High to Chip Enable Low	Min	25	25	30	30	ns
t _{EHGL}		Chip Enable High to Output Enable Low	Min	25	25	30	30	ns
t _{EHWH}	t _{WH}	Chip Enable High to Write Enable High	Min	0	0	0	0	ns
t _{ELEH}	t _{CP}	Chip Enable Low to Chip Enable High	Min	45	45	50	50	ns
t _{ELQV}		Chip Enable Low to Output Valid	Min	70	85	90	100	ns
t _{OVVPL} (1)(2)		Output Valid to V _{PP} Low	Min	0	0	0	0	ns
t _{QVWPL}		Data Valid to Write Protect Low Min		0	0	0	0	ns
t _{VPHEH} (1)	t _{VPS}	V _{PP} High to Chip Enable High Min		200	200	200	200	ns
t _{WLEL}	t _{CS}	Write Enable Low to Chip Enable Low		0	0	0	0	ns
t _{WPHEH}		Write Protect High to Chip Enable High Min		45	45	50	50	ns

^{1.} Sampled only, not 100% tested.

^{2.} Applicable if V_{PP} is seen as a logic input ($V_{PP} < 3.6 V$).

W, Ē, G

tPHWL
tPHEL
tPHGL

tPHGL

tPHUL
tPHGL
tPHGL

Al03537b

Figure 11. Power-Up and Reset AC waveforms

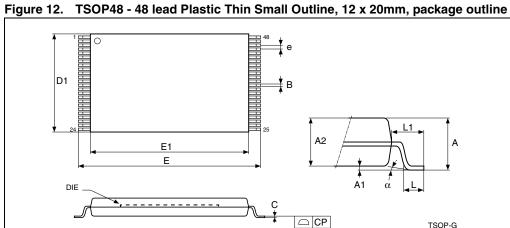
Table 19. Power-Up and Reset AC characteristics

Symbol	Parameter	Test Condi	N 1	Unit				
		1		70	85	90	10	
t _{PHWL}	Reset High to Write Enable Low, Chip Enable Low, Output Enable Low	During Program and Erase	Min	50	50	50	50	μs
t _{PHGL}	LOW	others	Min	30	30	30	30	ns
t _{PLPH} ⁽¹⁾⁽²⁾	Reset Low to Reset High		Min	100	100	100	100	ns
t _{VDHPH} (3)	Supply Voltages High to Reset High		Min	50	50	50	50	μs

- 1. The device Reset is possible but not guaranteed if t_{PLPH} < 100ns
- 2. Sampled only, not 100% tested.
- 3. It is important to assert $\overline{\text{RP}}$ in order to allow proper CPU initialization during power up or reset.

TSOP-G

Package mechanical 9



1. Drawing is not to scale.

TSOP48 - 48 lead Plastic Thin Small Outline, 12 x 20mm, package Table 20. mechanical data

modification data						
Symbol		millimeters			inches	
Symbol	Тур	Min	Max	Тур	Min	Max
А			1.200			0.0472
A1	0.100	0.050	0.150	0.0039	0.0020	0.0059
A2	1.000	0.950	1.050	0.0394	0.0374	0.0413
В	0.220	0.170	0.270	0.0087	0.0067	0.0106
С		0.100	0.210		0.0039	0.0083
CP			0.100			0.0039
D1	12.000	11.900	12.100	0.4724	0.4685	0.4764
Е	20.000	19.800	20.200	0.7874	0.7795	0.7953
E1	18.400	18.300	18.500	0.7244	0.7205	0.7283
е	0.500	-	-	0.0197	-	_
L	0.600	0.500	0.700	0.0236	0.0197	0.0276
L1	0.800			0.0315		
α	3°	0°	5°	3°	0°	5°

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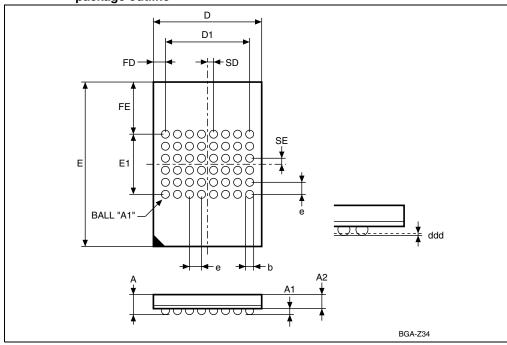


Figure 13. TFBGA48 6.39x10.5mm - 8x6 ball array, 0.75mm pitch, bottom view package outline

1. Drawing is not to scale.

Table 21. TFBGA48 6.39x10.5mm - 8x6 ball array, 0.75mm pitch, package mechanical data

Compleal		millimeters			inches	
Symbol	Тур	Min	Max	Тур	Min	Max
Α			1.200			0.0472
A1		0.260			0.0102	
A2			1.000			0.0394
b	0.400	0.350	0.450	0.0157	0.0138	0.0177
D	6.390	6.290	6.490	0.2516	0.2476	0.2555
D1	5.250	-	_	0.2067	-	_
ddd			0.100			0.0039
E	10.500	10.400	10.600	0.4134	0.4094	0.4173
E1	3.750	-	_	0.1476	-	_
е	0.750	_	_	0.0295	_	_
FD	0.570	-	_	0.0224	-	_
FE	3.375	-	-	0.1329	-	-
SD	0.375	-	-	0.0148	-	-
SE	0.375	-	_	0.0148	-	_

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Figure 14. TFBGA48 daisy chain - package connections (top view through package)

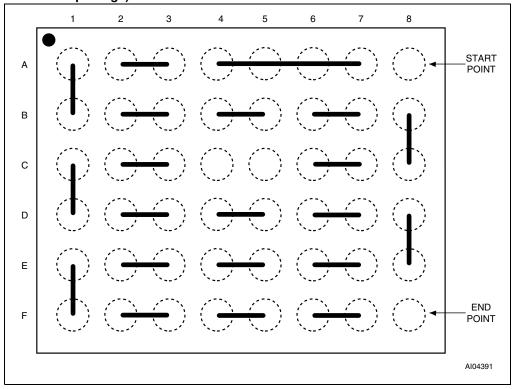


Figure 15. TFBGA48 daisy chain - PCB connections proposal (top view through package)

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10 Part numbering

Table 22. Ordering information scheme

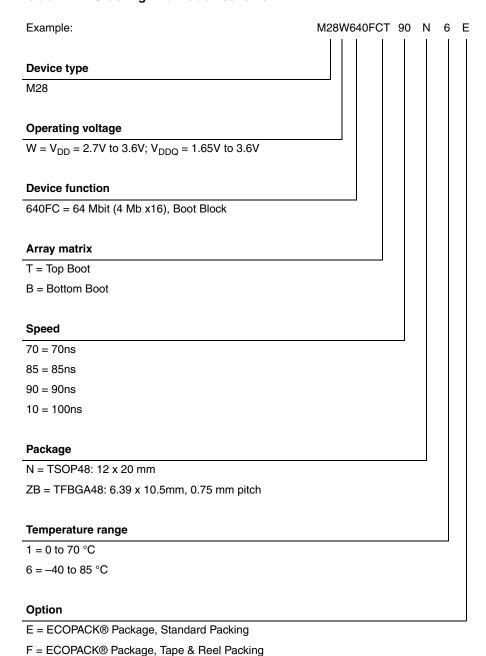
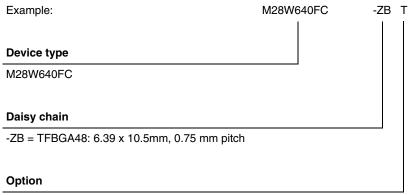


Table 23. Daisy Chain ordering scheme



E = ECOPACK® Package, Standard Packing

F = ECOPACK® Package, Tape & Reel Packing, 24mm

Devices are shipped from the factory with the memory content bits erased to '1'. For a list of available
options (Speed, Package, etc.) or for further information on any aspect of this device, please contact the
Numonyx Sales Office nearest to you.

Appendix A Block address tables

Table 24. Top Boot Block Addresses, M28W640FCT

#	Size (KWord)	Address range
0	4	3FF000-3FFFFF
1	4	3FE000-3FEFFF
2	4	3FD000-3FDFFF
3	4	3FC000-3FCFFF
4	4	3FB000-3FBFFF
5	4	3FA000-3FAFFF
6	4	3F9000-3F9FFF
7	4	3F8000-3F8FFF
8	32	3F0000-3F7FFF
9	32	3E8000-3EFFFF
10	32	3E0000-3E7FFF
11	32	3D8000-3DFFFF
12	32	3D0000-3D7FFF
13	32	3C8000-3CFFFF
14	32	3C0000-3C7FFF
15	32	3B8000-3BFFFF
16	32	3B0000-3B7FFF
17	32	3A8000-3AFFFF
18	32	3A0000-3A7FFF
19	32	398000-39FFFF
20	32	390000-397FFF
21	32	388000-38FFFF
22	32	380000-387FFF
23	32	378000-37FFFF
24	32	370000-377FFF
25	32	368000-36FFFF
26	32	360000-367FFF
27	32	358000-35FFFF
28	32	350000-357FFF
29	32	348000-34FFFF
30	32	340000-347FFF
31	32	338000-33FFFF

Table 24. Top Boot Block Addresses, M28W640FCT (continued)

#	Size (KWord)	Address range
32	32	330000-337FFF
33	32	328000-32FFFF
34	32	320000-327FFF
35	32	318000-31FFFF
36	32	310000-317FFF
37	32	308000-30FFFF
38	32	300000-307FFF
39	32	2F8000-2FFFFF
40	32	2F0000-2F7FFF
41	32	2E8000-2EFFFF
42	32	2E0000-2E7FFF
43	32	2D8000-2DFFFF
44	32	2D0000-2D7FFF
45	32	2C8000-2CFFFF
46	32	2C0000-2C7FFF
47	32	2B8000-2BFFFF
48	32	2B0000-2B7FFF
49	32	2A8000-2AFFFF
50	32	2A0000-2A7FFF
51	32	298000-29FFFF
52	32	290000-297FFF
53	32	288000-28FFFF
54	32	280000-287FFF
55	32	278000-27FFFF
56	32	270000-277FFF
57	32	268000-26FFFF
58	32	260000-267FFF
59	32	258000-25FFFF
60	32	250000-257FFF
61	32	248000-24FFFF
62	32	240000-247FFF
63	32	238000-23FFFF
64	32	230000-237FFF
65	32	228000-22FFFF
66	32	220000-227FFF

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Table 24. Top Boot Block Addresses, M28W640FCT (continued)

67 32 218000-21FFFF 68 32 200000-207FFF 70 32 200000-207FFF 71 32 1F8000-1FFFF 72 32 1F8000-1FFFF 73 32 1E8000-1EFFF 75 32 1D8000-1DFFFF 76 32 1D8000-1DFFFF 77 32 1C8000-1C7FFF 78 32 1C8000-1C7FFF 80 32 1B8000-1BFFFF 80 32 1B8000-1BFFFF 81 32 1B8000-1BFFFF 88 32 1C0000-1C7FFF 89 32 1B8000-1BFFFF 88 32 1FFFF 89 32 1B8000-1BFFFF	# #	Size (KWord)	Address range
68 32 210000-217FFF 69 32 208000-20FFFF 70 32 200000-207FFF 71 32 1F8000-1FFFFF 72 32 1F8000-1FFFF 73 32 1E8000-1EFFF 74 32 1D8000-1DFFF 75 32 1D8000-1DFFF 76 32 1D0000-1DFFF 77 32 1C8000-1CFFF 78 32 1B8000-1BFFF 79 32 1B8000-1BFFF 80 32 1B000-1AFFFF 81 32 1A8000-1AFFFF 82 32 1A0000-1AFFFF 83 32 198000-19FFFF 84 32 198000-19FFFF 85 32 188000-18FFFF 86 32 188000-18FFFF 87 32 178000-17FFF 88 32 178000-17FFF 90 32 168000-16FFFF 90 32 158000-15FFF </td <td>67</td> <td></td> <td>218000-21FFFF</td>	67		218000-21FFFF
69 32 208000-20FFF 70 32 200000-207FF 71 32 1F8000-1FFFF 72 32 1F0000-1FFFF 73 32 1E8000-1EFFF 74 32 1D8000-1DFFF 75 32 1D8000-1DFFF 76 32 1D0000-1DFFF 77 32 1C8000-1CFFF 78 32 1B8000-1BFFF 79 32 1B8000-1BFFF 80 32 1B0000-1BFFF 81 32 1A8000-1AFFF 82 32 1A9000-1FFFF 83 32 1B8000-1BFFF 84 32 19000-19FFF 85 32 18800-18FFF 86 32 188000-18FFF 87 32 178000-17FFF 88 32 178000-17FFF 89 32 168000-16FFF 90 32 168000-16FFF 91 32 158000-15FFF 92 32 158000-15FFF 93 32			
70 32 200000-207FFF 71 32 1F8000-1FFFFF 72 32 1F0000-1F7FFF 73 32 1E8000-1EFFF 74 32 1E0000-1FFFF 75 32 1D0000-1D7FFF 76 32 1D000-1CFFFF 77 32 1C8000-1CFFF 78 32 1B8000-1BFFFF 79 32 1B8000-1BFFFF 80 32 1B0000-1BFFFF 81 32 1A8000-1AFFFF 82 32 1A9000-19FFFF 83 32 198000-19FFFF 84 32 190000-19FFFF 85 32 188000-18FFFF 86 32 180000-18FFFF 87 32 178000-17FFFF 88 32 168000-16FFFF 90 32 168000-16FFFF 91 32 158000-15FFFF 92 32 150000-15FFFF 93 32 148000-			
71 32 1F8000-1FFFF 72 32 1F0000-1FFFF 73 32 1E8000-1EFFF 74 32 1E0000-1FFF 75 32 1D0000-1DFFF 76 32 1D0000-1FFF 77 32 1C8000-1FFF 78 32 1B8000-1FFF 80 32 1B0000-1FFF 81 32 1B0000-1FFF 82 32 1A0000-1AFFF 83 32 198000-19FFF 84 32 190000-19FFF 85 32 188000-18FFF 86 32 18000-18FFF 87 32 178000-17FFF 88 32 178000-17FFF 89 32 168000-16FFF 90 32 160000-16FFF 91 32 158000-15FFF 92 32 150000-15FFF 93 32 148000-14FFF 94 32 148000-14FFF			
73 32 1E8000-1EFFFF 74 32 1E0000-1DFFFF 75 32 1D8000-1DFFFF 76 32 1D0000-1DFFFF 77 32 1C8000-1CFFFF 78 32 1B8000-1BFFFF 79 32 1B8000-1BFFFF 80 32 1B0000-1FFFF 81 32 1A8000-1AFFFF 82 32 198000-19FFFF 83 32 198000-19FFFF 84 32 190000-19FFFF 85 32 188000-18FFFF 86 32 18000-18FFFF 87 32 178000-17FFFF 88 32 178000-17FFFF 89 32 168000-16FFFF 90 32 168000-16FFFF 91 32 158000-15FFFF 92 32 158000-15FFFF 93 32 148000-14FFFF 94 32 148000-14FFFF 96 32 13800			
74 32 1E0000-1E7FFF 75 32 1D8000-1DFFFF 76 32 1D0000-1D7FFF 77 32 1C8000-1CFFFF 78 32 1C0000-1C7FFF 79 32 1B8000-1BFFFF 80 32 1B0000-1BFFFF 81 32 1A8000-1AFFFF 82 32 198000-19FFFF 83 32 198000-19FFFF 84 32 190000-19FFFF 85 32 188000-18FFFF 86 32 18000-18FFFF 87 32 178000-17FFFF 89 32 168000-16FFFF 90 32 168000-16FFFF 91 32 158000-15FFFF 92 32 158000-15FFFF 93 32 148000-14FFFF 94 32 148000-14FFFF 95 32 138000-13FFFF 96 32 130000-137FFF 96 32 1280	72	32	1F0000-1F7FFF
74 32 1E0000-1E7FFF 75 32 1D8000-1DFFFF 76 32 1D0000-1D7FFF 77 32 1C8000-1CFFFF 78 32 1C0000-1C7FFF 79 32 1B8000-1BFFFF 80 32 1B0000-1BFFFF 81 32 1A8000-1AFFFF 82 32 198000-19FFFF 83 32 198000-19FFFF 84 32 190000-19FFFF 85 32 188000-18FFFF 86 32 18000-17FFFF 87 32 178000-17FFFF 89 32 168000-16FFFF 90 32 168000-16FFFF 91 32 158000-15FFFF 92 32 158000-15FFFF 93 32 148000-14FFFF 94 32 148000-14FFFF 95 32 138000-13FFFF 96 32 130000-137FFF 96 32 1280	73	32	1E8000-1EFFFF
76 32 1D0000-1D7FFF 77 32 1C8000-1CFFFF 78 32 1C0000-1C7FFF 79 32 1B8000-1BFFFF 80 32 1B0000-1BFFFF 81 32 1A8000-1AFFFF 82 32 1A9000-19FFF 83 32 198000-19FFF 84 32 190000-19FFF 85 32 188000-18FFF 86 32 180000-17FFF 87 32 178000-17FFF 88 32 170000-17FFF 89 32 168000-16FFFF 90 32 158000-15FFFF 91 32 158000-15FFFF 92 32 150000-15FFFF 93 32 148000-14FFFF 94 32 148000-13FFFF 95 32 138000-13FFFF 96 32 138000-12FFFF 98 32 128000-12FFFF 98 32 128000-12F	74	32	
77 32 1C8000-1CFFFF 78 32 1C0000-1C7FFF 79 32 1B8000-1BFFFF 80 32 1B0000-1B7FFF 81 32 1A8000-1AFFFF 82 32 1A9000-19FFF 83 32 199000-19FFF 84 32 190000-19FFF 85 32 188000-18FFF 86 32 180000-17FFF 87 32 178000-17FFF 89 32 168000-16FFFF 90 32 160000-16FFFF 91 32 158000-15FFFF 92 32 150000-15FFFF 93 32 148000-14FFFF 94 32 149000-14FFFF 95 32 138000-13FFFF 96 32 138000-12FFFF 98 32 128000-12FFFF 99 32 118000-11FFFF	75	32	1D8000-1DFFFF
78 32 1C0000-1C7FFF 79 32 1B8000-1BFFFF 80 32 1B0000-1B7FFF 81 32 1A8000-1AFFFF 82 32 198000-19FFF 83 32 198000-19FFF 84 32 190000-19FFF 85 32 188000-18FFFF 86 32 18000-18FFFF 87 32 178000-17FFF 88 32 170000-177FFF 89 32 168000-16FFFF 90 32 168000-15FFFF 91 32 158000-15FFFF 92 32 150000-15FFFF 93 32 148000-14FFFF 94 32 148000-13FFFF 95 32 138000-13FFFF 96 32 138000-12FFFF 97 32 128000-12FFFF 98 32 120000-127FFF 99 32 118000-11FFFF <td>76</td> <td>32</td> <td>1D0000-1D7FFF</td>	76	32	1D0000-1D7FFF
79 32 1B8000-1BFFFF 80 32 1B0000-1B7FFF 81 32 1A8000-1AFFFF 82 32 1A0000-1AFFFF 83 32 198000-19FFFF 84 32 190000-19FFF 85 32 188000-18FFFF 86 32 178000-17FFFF 87 32 178000-17FFFF 89 32 168000-16FFFF 90 32 160000-16FFFF 91 32 158000-15FFFF 92 32 158000-15FFFF 93 32 148000-14FFFF 94 32 148000-13FFFF 95 32 138000-13FFFF 96 32 130000-13FFFF 97 32 128000-12FFFF 98 32 120000-12FFFF 99 32 118000-11FFFF	77	32	1C8000-1CFFFF
80 32 1B0000-1B7FFF 81 32 1A8000-1AFFFF 82 32 1A0000-1A7FFF 83 32 198000-19FFFF 84 32 190000-197FFF 85 32 188000-18FFFF 86 32 178000-17FFF 87 32 178000-17FFF 88 32 170000-17FFF 89 32 168000-16FFFF 90 32 158000-15FFFF 91 32 158000-15FFFF 92 32 150000-157FFF 93 32 148000-14FFFF 94 32 148000-13FFFF 96 32 130000-137FFF 97 32 128000-12FFFF 98 32 120000-127FFF 99 32 118000-11FFFF	78	32	1C0000-1C7FFF
81 32 1A8000-1AFFFF 82 32 1A0000-1A7FFF 83 32 198000-19FFFF 84 32 190000-197FFF 85 32 188000-18FFFF 86 32 180000-187FFF 87 32 178000-17FFF 88 32 170000-17FFF 89 32 168000-16FFFF 90 32 160000-167FFF 91 32 158000-15FFFF 92 32 150000-157FFF 93 32 148000-14FFFF 94 32 148000-14FFFF 95 32 138000-13FFFF 96 32 130000-13FFFF 97 32 128000-12FFFF 98 32 120000-127FFF 99 32 118000-11FFFF	79	32	1B8000-1BFFFF
82 32 1A0000-1A7FFF 83 32 198000-19FFFF 84 32 190000-197FFF 85 32 188000-18FFFF 86 32 180000-187FFF 87 32 178000-17FFF 88 32 170000-177FFF 89 32 168000-16FFFF 90 32 160000-167FFF 91 32 158000-15FFFF 92 32 150000-157FFF 93 32 148000-14FFFF 94 32 140000-147FFF 95 32 138000-13FFFF 96 32 130000-137FFF 97 32 128000-12FFFF 98 32 120000-127FFF 99 32 118000-11FFFF	80	32	1B0000-1B7FFF
83 32 198000-19FFFF 84 32 190000-197FFF 85 32 188000-18FFFF 86 32 180000-187FFF 87 32 178000-17FFF 88 32 170000-177FFF 89 32 168000-16FFFF 90 32 158000-15FFFF 91 32 158000-15FFFF 92 32 150000-157FFF 93 32 148000-14FFFF 94 32 148000-13FFFF 95 32 138000-13FFFF 96 32 130000-137FFF 97 32 128000-12FFFF 98 32 120000-127FFF 99 32 118000-11FFFF	81	32	1A8000-1AFFFF
84 32 190000-197FFF 85 32 188000-18FFFF 86 32 180000-187FFF 87 32 178000-17FFFF 88 32 170000-177FFF 89 32 168000-16FFFF 90 32 158000-15FFFF 91 32 158000-15FFFF 92 32 150000-157FFF 93 32 148000-14FFFF 94 32 149000-147FFF 95 32 138000-13FFFF 96 32 128000-12FFFF 98 32 128000-12FFFF 99 32 118000-11FFFF	82	32	1A0000-1A7FFF
85 32 188000-18FFFF 86 32 180000-187FFF 87 32 178000-17FFF 88 32 170000-177FFF 89 32 168000-16FFFF 90 32 160000-167FFF 91 32 158000-15FFFF 92 32 150000-157FFF 93 32 148000-14FFFF 94 32 138000-13FFFF 95 32 138000-13FFFF 96 32 130000-13FFFF 97 32 128000-12FFFF 98 32 120000-127FFF 99 32 118000-11FFFF	83	32	198000-19FFFF
86 32 180000-187FFF 87 32 178000-17FFFF 88 32 170000-177FFF 89 32 168000-16FFFF 90 32 160000-167FFF 91 32 158000-15FFFF 92 32 150000-157FFF 93 32 148000-14FFFF 94 32 140000-147FFF 95 32 138000-13FFFF 96 32 130000-137FFF 97 32 128000-12FFFF 98 32 120000-127FFF 99 32 118000-11FFFF	84	32	190000-197FFF
87 32 178000-17FFF 88 32 170000-177FFF 89 32 168000-16FFFF 90 32 160000-167FFF 91 32 158000-15FFFF 92 32 150000-157FFF 93 32 148000-14FFFF 94 32 140000-147FFF 95 32 138000-13FFFF 96 32 130000-12FFFF 97 32 128000-12FFFF 98 32 120000-12FFFF 99 32 118000-11FFFF	85	32	188000-18FFFF
88 32 170000-177FFF 89 32 168000-16FFFF 90 32 160000-167FFF 91 32 158000-15FFFF 92 32 150000-157FFF 93 32 148000-14FFFF 94 32 140000-147FFF 95 32 138000-13FFFF 96 32 128000-12FFFF 98 32 120000-127FFF 99 32 118000-11FFFF	86	32	180000-187FFF
89 32 168000-16FFFF 90 32 160000-167FFF 91 32 158000-15FFFF 92 32 150000-157FFF 93 32 148000-14FFFF 94 32 140000-147FFF 95 32 138000-13FFFF 96 32 130000-137FFF 97 32 128000-12FFFF 98 32 120000-127FFF 99 32 118000-11FFFF	87	32	178000-17FFFF
90 32 160000-167FFF 91 32 158000-15FFFF 92 32 150000-157FFF 93 32 148000-14FFFF 94 32 140000-147FFF 95 32 138000-13FFFF 96 32 130000-137FFF 97 32 128000-12FFFF 98 32 120000-127FFF 99 32 118000-11FFFF	88	32	170000-177FFF
91 32 158000-15FFFF 92 32 150000-157FFF 93 32 148000-14FFFF 94 32 140000-147FFF 95 32 138000-13FFFF 96 32 130000-137FFF 97 32 128000-12FFFF 98 32 120000-127FFF 99 32 118000-11FFFF	89	32	168000-16FFFF
92 32 150000-157FFF 93 32 148000-14FFFF 94 32 140000-147FFF 95 32 138000-13FFFF 96 32 130000-137FFF 97 32 128000-12FFFF 98 32 120000-127FFF 99 32 118000-11FFFF	90	32	160000-167FFF
93 32 148000-14FFFF 94 32 140000-147FFF 95 32 138000-13FFFF 96 32 130000-137FFF 97 32 128000-12FFFF 98 32 120000-127FFF 99 32 118000-11FFFF	91	32	158000-15FFFF
94 32 140000-147FFF 95 32 138000-13FFFF 96 32 130000-137FFF 97 32 128000-12FFFF 98 32 120000-127FFF 99 32 118000-11FFFF	92	32	150000-157FFF
95 32 138000-13FFFF 96 32 130000-137FFF 97 32 128000-12FFFF 98 32 120000-127FFF 99 32 118000-11FFFF	93	32	148000-14FFFF
96 32 130000-137FFF 97 32 128000-12FFFF 98 32 120000-127FFF 99 32 118000-11FFFF	94	32	140000-147FFF
97 32 128000-12FFF 98 32 120000-127FF 99 32 118000-11FFFF	95	32	138000-13FFFF
98 32 120000-127FFF 99 32 118000-11FFFF	96	32	130000-137FFF
99 32 118000-11FFFF	97	32	128000-12FFFF
	98	32	120000-127FFF
100 32 110000-117FFF	99	32	118000-11FFFF
	100	32	110000-117FFF
101 32 108000-10FFFF	101	32	108000-10FFFF

Table 24. Top Boot Block Addresses, M28W640FCT (continued)

#	Size (KWord)	Address range
102	32	100000-107FFF
103	32	0F8000-0FFFFF
104	32	0F0000-0F7FFF
105	32	0E8000-0EFFFF
106	32	0E0000-0E7FFF
107	32	0D8000-0DFFFF
108	32	0D0000-0D7FFF
109	32	0C8000-0CFFFF
110	32	0C0000-0C7FFF
111	32	0B8000-0BFFFF
112	32	0B0000-0B7FFF
113	32	0A8000-0AFFFF
114	32	0A0000-0A7FFF
115	32	098000-09FFFF
116	32	090000-097FFF
117	32	088000-08FFFF
118	32	080000-087FFF
119	32	078000-07FFFF
120	32	070000-077FFF
121	32	068000-06FFFF
122	32	060000-067FFF
123	32	058000-05FFFF
124	32	050000-057FFF
125	32	048000-04FFFF
126	32	040000-047FFF
127	32	038000-03FFFF
128	32	030000-037FFF
129	32	028000-02FFFF
130	32	020000-027FFF
131	32	018000-01FFFF
132	32	010000-017FFF
133	32	008000-00FFFF
134	32	000000-007FFF

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Table 25. Bottom Boot Block Addresses, M28W640FCB

#	Size (KWord)	Address Range
134	32	3F8000-3FFFFF
133	32	3F0000-3F7FFF
132	32	3E8000-3EFFFF
131	32	3E0000-3E7FFF
130	32	3D8000-3DFFFF
129	32	3D0000-3D7FFF
128	32	3C8000-3CFFFF
127	32	3C0000-3C7FFF
126	32	3B8000-3BFFFF
125	32	3B0000-3B7FFF
124	32	3A8000-3AFFFF
123	32	3A0000-3A7FFF
122	32	398000-39FFFF
121	32	390000-397FFF
120	32	388000-38FFFF
119	32	380000-387FFF
118	32	378000-37FFFF
117	32	370000-377FFF
116	32	368000-36FFFF
115	32	360000-367FFF
114	32	358000-35FFFF
113	32	350000-357FFF
112	32	348000-34FFFF
111	32	340000-347FFF
110	32	338000-33FFFF
109	32	330000-337FFF
108	32	328000-32FFFF
107	32	320000-327FFF
106	32	318000-31FFFF
105	32	310000-317FFF
104	32	308000-30FFFF
103	32	300000-307FFF
102	32	2F8000-2FFFFF
101	32	2F0000-2F7FFF
100	32	2E8000-2EFFFF

Table 25. Bottom Boot Block Addresses, M28W640FCB (continued)

99 32 2E0000-2E7FFF 98 32 2D000-2D7FFF 96 32 2C0000-2C7FFF 95 32 2C0000-2C7FFF 97 32 2E8000-2BFFF 98 32 2E8000-2BFFF 99 32 2E8000-2BFFF 99 32 2E8000-2BFFF 90 32 2E8000-2BFFF 91 32 2E8000-2BFFF 90 32 2E8000-2BFFF 89 32 2E8000-2BFFF 89 32 2E8000-2BFFF 89 32 2E8000-2BFFF 89 32 2E8000-2FFFF 88 32 2E8000-2FFFF 89 32 2E8000-2FFFF 80 32 2E8000-2FFFF 81 32 2E8000-2FFFF 82 32 2E8000-2FFFF 83 32 2E8000-2FFFF 84 32 2E8000-2FFFF 85 32 2E8000-2FFFF 86 32 2E8000-2FFFF 87 32 2E8000-2FFFF 88 32 2E8000-2FFFF 89 32 2E8000-2FFFF 80 32 2E8000-2FFFF 80 32 2E8000-2FFFF 80 32 2E8000-2FFFF 81 32 2E8000-2FFFF 81 32 2E8000-2FFFF 82 32 2E8000-2FFFF 83 32 2E8000-2FFFF 84 32 2E8000-2FFFF 85 32 2E8000-2FFFF 86 32 2E8000-2FFFF 87 32 2E8000-2FFFF 88 32 2E8000-2FFFF 89 32 2E8000-2FFFF	#	Size (KWord)	Address Range			
97 32 2D000-2D7FFF 96 32 2C8000-2CFFFF 95 32 2C0000-2C7FFF 94 32 2B8000-2BFFFF 93 32 2A8000-2AFFFF 91 32 2A0000-2AFFFF 89 32 298000-29FFFF 89 32 298000-29FFFF 89 32 288000-28FFFF 89 32 288000-28FFFF 88 32 288000-28FFFF 88 32 288000-28FFFF 88 32 278000-27FFF 88 32 278000-27FFF 89 32 268000-26FFFF 89 32 258000-26FFFF 89 32 258000-25FFFF 80 32 258000-25FFFF 80 32 248000-24FFFF 80 32 248000-24FFFF 80 32 248000-24FFFF 81 32 250000-25FFFF 82 250000-25FFFF 83 32 250000-25FFFF 84 32 250000-25FFFF 85 32 250000-25FFFF 86 32 250000-25FFFF 87 32 250000-25FFFF 87 32 2500000-25FFFF 89 32 250000-25FFFF	99	32	2E0000-2E7FFF			
96 32 2C8000-2CFFFF 95 32 2C0000-2C7FFF 94 32 2B8000-2BFFFF 93 32 2A8000-2AFFFF 99 32 2A8000-2AFFFF 90 32 298000-29FFFF 89 32 298000-29FFFF 89 32 288000-28FFFF 88 32 288000-28FFFF 88 32 288000-28FFFF 88 32 278000-27FFF 88 32 278000-27FFF 89 32 268000-26FFFF 80 32 258000-25FFFF 81 32 258000-25FFFF 81 32 258000-25FFFF 81 32 258000-25FFFF 81 32 248000-24FFFF 82 32 248000-24FFFF 83 32 248000-24FFFF 79 32 240000-24FFFF 79 32 228000-23FFFF 77 32 228000-23FFFF 78 32 228000-22FFFF 79 32 228000-22FFFF 71 32 228000-22FFFF 72 32 228000-22FFFF 73 32 218000-21FFFF 74 32 218000-21FFFF 75 32 228000-20FFFF 76 32 118000-1FFFFF 77 32 118000-1FFFFF 78 32 118000-1FFFFF 79 32 118000-1FFFFF 70 32 118000-1FFFFF 71 32 118000-1FFFFF 71 32 118000-1FFFFF 72 32 118000-1FFFFF 73 32 118000-1FFFFF	98	32	2D8000-2DFFFF			
95 32 2C0000-2C7FFF 94 32 2B8000-2BFFFF 93 32 2A8000-2AFFFF 99 32 2A8000-2AFFFF 90 32 298000-29FFFF 88 32 29000-29FFFF 88 32 288000-28FFFF 88 32 288000-28FFFF 88 32 278000-27FFF 88 32 278000-27FFF 88 32 268000-26FFFF 89 32 268000-26FFFF 89 32 268000-26FFFF 89 32 268000-26FFFF 89 32 258000-25FFFF 80 32 258000-25FFFF 81 32 258000-25FFFF 81 32 258000-25FFFF 82 32 258000-25FFFF 83 32 248000-24FFFF 84 32 248000-24FFFF 85 32 248000-24FFFF 76 32 248000-23FFFF 77 32 258000-25FFFF 78 32 258000-25FFFF 79 32 240000-27FFF 70 32 258000-27FFF 71 32 258000-27FFF 72 32 258000-27FFF 73 32 258000-27FFF 74 32 218000-21FFFF 75 32 228000-27FFF 76 32 218000-21FFFF 77 32 218000-21FFFF 78 32 218000-21FFFF 79 32 218000-20FFFF 70 32 1F8000-1FFFFF 70 32 1F8000-1FFFFF 70 32 1F8000-1FFFFF 70 32 1F8000-1FFFFF 71 32 1E8000-1FFFFF 71 32 1E8000-1FFFFF 72 32 1E8000-1FFFFF 73 32 1E8000-1FFFFF	97	32	2D0000-2D7FFF			
94 32 2B8000-2BFFFF 93 32 2A8000-2AFFFF 91 32 2A8000-2AFFFF 89 32 298000-29FFFF 88 32 288000-28FFFF 86 32 278000-27FFF 88 32 268000-26FFFF 88 32 268000-26FFFF 88 32 268000-26FFFF 88 32 268000-26FFFF 89 32 268000-26FFFF 89 32 268000-26FFFF 89 32 268000-26FFFF 89 32 268000-26FFFF 80 32 258000-25FFFF 81 32 258000-25FFFF 81 32 248000-24FFFF 82 32 248000-24FFFF 83 32 248000-24FFFF 84 32 248000-24FFFF 85 32 248000-24FFFF 86 32 248000-24FFFF 87 32 240000-27FFF 88 32 228000-22FFFF 89 32 240000-27FFF 89 32 240000-27FFF 80 32 228000-22FFFF 80 32 218000-21FFFF 80 32 218000-11FFFF 80 32 118000-11FFFFF 80 32 118000-11FFFFF	96	32	2C8000-2CFFFF			
93 32 2B0000-2B7FFF 92 32 2A8000-2AFFFF 91 32 298000-29FFFF 88 32 288000-28FFFF 86 32 278000-27FFF 81 32 268000-27FFF 82 32 268000-27FFF 83 32 268000-27FFF 84 32 268000-27FFF 85 32 270000-27FFF 86 32 258000-25FFF 87 32 268000-25FFF 88 32 258000-25FFF 89 32 248000-25FFF 79 32 240000-27FFF 76 32 230000-23FFF 77 32 230000-23FFF 78 32 228000-22FFF 79 32 240000-27FFF 79 32 240000-27FFF 70 32 230000-27FFF 71 32 230000-27FFF 75 32 220000-27FFF 76 32 220000-27FFF 77 32 218000-21FFF 78 32 218000-21FFF 79 32 218000-21FFFF 70 32 218000-21FFFF 71 32 200000-207FFF 72 32 200000-207FFF 73 32 1F8000-1FFFF 74 32 1F8000-1FFFF 75 32 1F8000-1FFFF 76 32 1F8000-1FFFF 77 32 1F8000-1FFFF	95	32	2C0000-2C7FFF			
92 32 2A8000-2AFFFF 91 32 298000-29FFF 89 32 298000-29FFF 88 32 288000-28FFFF 86 32 278000-27FFF 85 32 270000-27FFF 81 32 268000-26FFFF 82 32 258000-26FFFF 83 32 258000-26FFFF 84 32 268000-26FFFF 85 32 260000-26FFFF 87 32 248000-25FFFF 88 32 248000-25FFF 89 32 248000-25FFF 79 32 240000-27FFF 76 32 230000-23FFF 77 32 230000-23FFF 78 32 228000-22FFF 79 32 218000-21FFF 79 32 218000-21FFF 70 32 218000-21FFF 71 32 200000-27FFF 72 32 200000-27FFF 73 32 18000-21FFF 74 32 218000-21FFF 75 32 200000-27FFF 76 32 218000-21FFFF 77 32 218000-21FFFF 78 32 218000-21FFFF 79 32 218000-21FFFF 70 32 168000-16FFFF 71 32 200000-207FFF 71 32 218000-16FFFF 72 32 168000-16FFFF 73 32 168000-16FFFF 74 32 168000-16FFFF 75 32 168000-16FFFF	94	32	2B8000-2BFFFF			
91 32 240000-247FFF 89 32 298000-297FFF 88 32 288000-28FFFF 86 32 278000-27FFF 81 32 268000-27FFF 82 32 268000-267FFF 83 32 268000-267FFF 84 32 268000-267FFF 85 32 268000-267FFF 86 32 268000-267FFF 87 32 268000-257FFF 88 32 268000-257FFF 89 32 248000-247FFF 79 32 240000-247FFF 76 32 228000-227FFF 77 32 220000-227FFF 78 32 218000-217FFF 79 32 210000-217FFF 70 32 218000-217FFF 71 32 200000-207FFF 72 32 218000-217FFF 73 32 218000-217FFF 74 32 218000-217FFF 75 32 218000-217FFF 76 32 218000-217FFF 77 32 218000-217FFF 78 32 218000-217FFF 79 32 218000-217FFF 70 32 158000-157FFF 69 32 150000-157FFF 69 32 150000-157FFF 66 32 150000-157FFF	93	32	2B0000-2B7FFF			
90 32 298000-29FFFF 89 32 28000-28FFFF 86 32 278000-27FFF 81 32 268000-26FFFF 82 32 268000-26FFFF 83 32 268000-26FFFF 84 32 268000-26FFFF 85 32 268000-26FFFF 86 32 268000-26FFFF 87 32 268000-27FFF 88 32 268000-26FFFF 89 32 268000-27FFF 80 32 278000-27FFF	92	32	2A8000-2AFFFF			
89 32 290000-297FFF 88 32 288000-28FFF 87 32 280000-27FFF 86 32 278000-27FFF 85 32 268000-26FFF 84 32 268000-26FFF 82 32 258000-25FFF 81 32 250000-25FFF 80 32 248000-24FFF 79 32 240000-247FFF 78 32 238000-23FFF 77 32 230000-23FFF 76 32 228000-22FFFF 74 32 218000-21FFF 73 32 218000-21FFF 72 32 208000-20FFF 71 32 208000-20FFF 71 32 208000-20FFF 70 32 1F8000-1FFFF 69 32 1F8000-1EFFFF 67 32 1E8000-1EFFFF 66 32 1D8000-1DFFFF	91	32	2A0000-2A7FFF			
88 32 288000-28FFFF 87 32 280000-287FFF 86 32 278000-27FFFF 85 32 270000-27FFF 84 32 268000-26FFF 83 32 258000-25FFF 81 32 258000-25FFF 80 32 248000-24FFF 79 32 240000-247FFF 78 32 238000-23FFF 77 32 230000-23FFF 76 32 228000-22FFFF 75 32 228000-22FFFF 74 32 218000-21FFFF 73 32 210000-21FFFF 71 32 208000-20FFFF 71 32 208000-20FFFF 70 32 1F8000-1FFFFF 69 32 1F8000-1EFFFF 67 32 1E8000-1EFFFF 66 32 1D8000-1DFFFF	90	32	298000-29FFFF			
87 32 280000-287FFF 86 32 278000-277FFF 85 32 270000-277FFF 84 32 268000-26FFFF 83 32 260000-26FFFF 82 32 258000-25FFFF 81 32 248000-24FFFF 79 32 248000-24FFFF 78 32 238000-23FFFF 76 32 228000-22FFFF 75 32 228000-22FFFF 74 32 218000-21FFFF 73 32 210000-21FFFF 71 32 200000-20FFFF 70 32 1F8000-1FFFFF 69 32 1F0000-1FFFFF 68 32 1E8000-1EFFFF 66 32 1D800-1DFFFF	89	32	290000-297FFF			
86 32 278000-27FFF 85 32 270000-277FFF 84 32 268000-26FFFF 83 32 260000-267FFF 82 32 258000-25FFFF 81 32 250000-25FFFF 80 32 248000-24FFFF 79 32 240000-247FFF 78 32 238000-23FFF 76 32 228000-22FFFF 75 32 220000-22FFFF 74 32 218000-21FFFF 72 32 208000-20FFFF 71 32 200000-20FFFF 70 32 1F8000-1FFFFF 69 32 1F0000-1FFFFF 68 32 1E8000-1EFFFF 66 32 1D8000-1DFFFF	88	32	288000-28FFFF			
85 32 270000-277FFF 84 32 268000-26FFFF 83 32 260000-267FFF 82 32 258000-25FFFF 81 32 250000-257FFF 80 32 248000-24FFFF 79 32 240000-247FFF 78 32 238000-23FFF 77 32 230000-237FFF 76 32 228000-22FFFF 75 32 220000-22FFFF 74 32 218000-21FFFF 73 32 210000-21FFF 71 32 200000-20FFFF 70 32 1F8000-1FFFFF 69 32 1F0000-1F7FFF 68 32 1E8000-1EFFFF 67 32 1E0000-1DFFFF	87	32	280000-287FFF			
84 32 268000-26FFF 83 32 260000-267FFF 82 32 258000-25FFFF 81 32 250000-257FFF 80 32 248000-24FFF 79 32 240000-247FFF 78 32 238000-23FFF 77 32 230000-23FFF 76 32 228000-22FFFF 74 32 218000-21FFFF 73 32 210000-21FFFF 72 32 208000-20FFFF 70 32 1F8000-1FFFFF 69 32 1F0000-1FFFFF 68 32 1E8000-1EFFFF 67 32 1D8000-1DFFFFF	86	32	278000-27FFFF			
83 32 260000-267FFF 82 32 258000-25FFFF 81 32 250000-257FFF 80 32 248000-24FFFF 79 32 240000-247FFF 78 32 238000-23FFF 76 32 228000-22FFFF 75 32 220000-227FFF 74 32 218000-21FFFF 73 32 210000-217FFF 72 32 208000-20FFFF 71 32 200000-207FFF 70 32 1F8000-1FFFFF 69 32 1F0000-1FFFFF 68 32 1E8000-1EFFFF 67 32 1D8000-1DFFFF	85	32	270000-277FFF			
82 32 258000-25FFFF 81 32 250000-257FFF 80 32 248000-24FFFF 79 32 238000-23FFFF 77 32 230000-237FFF 76 32 228000-22FFFF 75 32 220000-227FFF 74 32 218000-21FFFF 73 32 210000-217FFF 72 32 208000-20FFFF 71 32 200000-20FFFF 70 32 1F8000-1FFFFF 69 32 1F0000-1FFFFF 68 32 1E8000-1EFFFF 67 32 1E0000-1DFFFF	84	32	268000-26FFFF			
81 32 250000-257FFF 80 32 248000-24FFFF 79 32 240000-247FFF 78 32 238000-23FFF 77 32 230000-237FFF 76 32 228000-22FFFF 75 32 218000-21FFFF 74 32 218000-21FFFF 73 32 210000-21FFFF 71 32 208000-20FFFF 70 32 1F8000-1FFFFF 69 32 1F0000-1FFFFF 68 32 1E8000-1EFFFF 67 32 1E0000-1DFFFF	83	32	260000-267FFF			
80 32 248000-24FFFF 79 32 240000-247FFF 78 32 238000-23FFF 77 32 230000-23FFF 76 32 228000-22FFF 75 32 220000-227FFF 74 32 218000-21FFFF 73 32 210000-217FFF 72 32 208000-20FFFF 71 32 200000-207FFF 70 32 1F8000-1FFFFF 69 32 1F0000-1FFFFF 68 32 1E8000-1EFFFF 67 32 1E0000-1E7FFF 66 32 1D8000-1DFFFF	82	32	258000-25FFFF			
79 32 240000-247FFF 78 32 238000-237FFF 77 32 230000-237FFF 76 32 228000-22FFF 75 32 220000-227FFF 74 32 218000-21FFF 73 32 210000-217FFF 72 32 208000-20FFFF 71 32 200000-207FFF 70 32 1F8000-1FFFFF 69 32 1F0000-1FFFFF 68 32 1E8000-1EFFFF 67 32 1E0000-1DFFFF	81	32	250000-257FFF			
78 32 238000-23FFF 77 32 230000-237FFF 76 32 228000-22FFFF 75 32 220000-227FFF 74 32 218000-21FFFF 73 32 210000-217FFF 72 32 208000-20FFFF 71 32 200000-207FFF 70 32 1F8000-1FFFFF 69 32 1F0000-1FFFFF 68 32 1E8000-1EFFFF 67 32 1E0000-1E7FFF 66 32 1D8000-1DFFFF	80	32	248000-24FFFF			
77 32 230000-237FFF 76 32 228000-22FFFF 75 32 220000-227FFF 74 32 218000-21FFFF 73 32 210000-217FFF 72 32 208000-20FFFF 71 32 200000-207FFF 70 32 1F8000-1FFFF 69 32 1F0000-1F7FF 68 32 1E8000-1EFFFF 67 32 1E0000-1E7FFF 66 32 1D8000-1DFFFF	79	32	240000-247FFF			
76 32 228000-22FFF 75 32 220000-227FFF 74 32 218000-21FFFF 73 32 210000-217FFF 72 32 208000-20FFFF 71 32 200000-207FFF 70 32 1F8000-1FFFFF 69 32 1E8000-1EFFFF 67 32 1E0000-1E7FFF 66 32 1D8000-1DFFFF	78	32	238000-23FFFF			
75 32 220000-227FFF 74 32 218000-21FFFF 73 32 210000-217FFF 72 32 208000-20FFFF 71 32 200000-207FFF 70 32 1F8000-1FFFFF 69 32 1F0000-1F7FFF 68 32 1E8000-1EFFFF 67 32 1D8000-1DFFFF	77	32	230000-237FFF			
74 32 218000-21FFFF 73 32 210000-217FFF 72 32 208000-20FFFF 71 32 200000-207FFF 70 32 1F8000-1FFFFF 69 32 1F0000-1FFFFF 68 32 1E8000-1EFFFF 67 32 1E0000-1E7FFF 66 32 1D8000-1DFFFF	76	32	228000-22FFFF			
73 32 210000-217FFF 72 32 208000-20FFF 71 32 200000-207FFF 70 32 1F8000-1FFFFF 69 32 1F0000-1F7FFF 68 32 1E8000-1EFFFF 67 32 1E0000-1E7FFF 66 32 1D8000-1DFFFF	75	32	220000-227FFF			
72 32 208000-20FFFF 71 32 200000-207FFF 70 32 1F8000-1FFFFF 69 32 1F0000-1F7FFF 68 32 1E8000-1EFFFF 67 32 1E0000-1E7FFF 66 32 1D8000-1DFFFF	74	32	218000-21FFFF			
71 32 200000-207FFF 70 32 1F8000-1FFFFF 69 32 1F0000-1F7FFF 68 32 1E8000-1EFFFF 67 32 1E0000-1E7FFF 66 32 1D8000-1DFFFF	73	32	210000-217FFF			
70 32 1F8000-1FFFFF 69 32 1F0000-1F7FFF 68 32 1E8000-1EFFFF 67 32 1E0000-1E7FFF 66 32 1D8000-1DFFFF	72	32	208000-20FFFF			
69 32 1F0000-1F7FFF 68 32 1E8000-1EFFFF 67 32 1E0000-1E7FFF 66 32 1D8000-1DFFFF	71	32	200000-207FFF			
68 32 1E8000-1EFFFF 67 32 1E0000-1E7FFF 66 32 1D8000-1DFFFF	70	32	1F8000-1FFFFF			
67 32 1E0000-1E7FFF 66 32 1D8000-1DFFFF	69	32	1F0000-1F7FFF			
66 32 1D8000-1DFFFF	68	32	1E8000-1EFFFF			
	67	32	1E0000-1E7FFF			
65 32 1D0000-1D7FFF	66	32	1D8000-1DFFFF			
	65	32	1D0000-1D7FFF			

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Table 25. Bottom Boot Block Addresses, M28W640FCB (continued)

#	Size (KWord)	Address Range
64	32	1C8000-1CFFFF
63	32	1C0000-1C7FFF
62	32	1B8000-1BFFFF
61	32	1B0000-1B7FFF
60	32	1A8000-1AFFFF
59	32	1A0000-1A7FFF
58	32	198000-19FFFF
57	32	190000-197FFF
56	32	188000-18FFFF
55	32	180000-187FFF
54	32	178000-17FFFF
53	32	170000-177FFF
52	32	168000-16FFFF
51	32	160000-167FFF
50	32	158000-15FFFF
49	32	150000-157FFF
48	32	148000-14FFFF
47	32	140000-147FFF
46	32	138000-13FFFF
45	32	130000-137FFF
44	32	128000-12FFFF
43	32	120000-127FFF
42	32	118000-11FFFF
41	32	110000-117FFF
40	32	108000-10FFFF
39	32	100000-107FFF
38	32	0F8000-0FFFFF
37	32	0F0000-0F7FFF
36	32	0E8000-0EFFFF
35	32	0E0000-0E7FFF
34	32	0D8000-0DFFFF
33	32	0D0000-0D7FFF
32	32	0C8000-0CFFFF
31	32	0C0000-0C7FFF
30	32	0B8000-0BFFFF

Table 25. Bottom Boot Block Addresses, M28W640FCB (continued)

#	Size (KWord)	Address Range
29	32	0B0000-0B7FFF
28	32	0A8000-0AFFFF
27	32	0A0000-0A7FFF
26	32	098000-09FFFF
25	32	090000-097FFF
24	32	088000-08FFFF
23	32	080000-087FFF
22	32	078000-07FFFF
21	32	070000-077FFF
20	32	068000-06FFFF
19	32	060000-067FFF
18	32	058000-05FFFF
17	32	050000-057FFF
16	32	048000-04FFFF
15	32	040000-047FFF
14	32	038000-03FFFF
13	32	030000-037FFF
12	32	028000-02FFFF
11	32	020000-027FFF
10	32	018000-01FFFF
9	32	010000-017FFF
8	32	008000-00FFFF
7	4	007000-007FFF
6	4	006000-006FFF
5	4	005000-005FFF
4	4	004000-004FFF
3	4	003000-003FFF
2	4	002000-002FFF
1	4	001000-001FFF
0	4	000000-000FFF

Appendix B Common Flash Interface (CFI)

The Common Flash Interface is a JEDEC approved, standardized data structure that can be read from the Flash memory device. It allows a system software to query the device to determine various electrical and timing parameters, density information and functions supported by the memory. The system can interface easily with the device, enabling the software to upgrade itself when necessary.

When the CFI Query Command (RCFI) is issued the device enters CFI Query mode and the data structure is read from the memory. Tables 26, 27, 28, 29, 30 and 31 show the addresses used to retrieve the data.

The CFI data structure also contains a security area where a 64 bit unique security number is written (see *Table 31: Security code area*). This area can be accessed only in Read mode by the final user. It is impossible to change the security number after it has been written by Numonyx. Issue a Read command to return to Read mode.

Table 26. Query Structure Overview⁽¹⁾

Offset	Sub-section Name	Description
00h	Reserved	Reserved for algorithm-specific information
10h	CFI Query Identification String	Command set ID and algorithm data offset
1Bh	System Interface Information	Device timing & voltage information
27h	Device Geometry Definition	Flash device layout
Р	Primary Algorithm-specific Extended Query table	Additional information specific to the Primary Algorithm (optional)
А	Alternate Algorithm-specific Extended Query table	Additional information specific to the Alternate Algorithm (optional)

^{1.} Query data are always presented on the lowest order data outputs.

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Table 27. CFI Query Identification String⁽¹⁾

Offset	Data	Description	Value
00h	0020h	Manufacturer code	Numonyx
01h	8848h 8849h	Device code	Top Bottom
02h-0Fh	reserved	Reserved	
10h	0051h		"Q"
11h	0052h	Query Unique ASCII String "QRY"	"R"
12h	0059h		"Y"
13h	0003h	Primary Algorithm Command Set and Control Interface ID code 16	Intel
14h	0000h	bit ID code defining a specific algorithm	compatibl e
15h	0035h	Address for Primary Algorithm extended Overy table (see Table 20)	P = 35h
16h	0000h	Address for Primary Algorithm extended Query table (see <i>Table 29</i>)	P = 35f1
17h	0000h	Alternate Vendor Command Set and Control Interface ID code	
18h	0000h	second vendor - specified algorithm supported (0000h means none exists)	NA
19h	0000h	Address for Alternate Algorithm extended Query table	NA
1Ah	0000h	(0000h means none exists)	INA

^{1.} Query data are always presented on the lowest order data outputs (DQ7-DQ0) only. DQ8-DQ15 are '0'.

Table 28. CFI Query System Interface Information

Offset	Data	Description	Value
1Bh	0027h	V _{DD} Logic Supply Minimum Program/Erase or Write voltage bit 7 to 4BCD value in volts bit 3 to 0BCD value in 100 mV	2.7V
1Ch	0036h	V _{DD} Logic Supply Maximum Program/Erase or Write voltage bit 7 to 4BCD value in volts bit 3 to 0BCD value in 100 mV	3.6V
1Dh	00B4h	V _{PP} [Programming] Supply Minimum Program/Erase voltage bit 7 to 4HEX value in volts bit 3 to 0BCD value in 100 mV	11.4V
1Eh	00C6h	V _{PP} [Programming] Supply Maximum Program/Erase voltage bit 7 to 4HEX value in volts bit 3 to 0BCD value in 100 mV	12.6V
1Fh	0004h	Typical time-out per single word program = 2 ⁿ μs	16µs
20h	0004h	Typical time-out for Double/Quadruple Word Program = 2 ⁿ µs	16µs
21h	000Ah	Typical time-out per individual block erase = 2 ⁿ ms	1s
22h	0000h	Typical time-out for full chip erase = 2 ⁿ ms	NA
23h	0005h	Maximum time-out for Word program = 2 ⁿ times typical	512µs
24h	0005h	Maximum time-out for Double/Quadruple Word Program = 2 ⁿ times typical	512µs
25h	0003h	Maximum time-out per individual block erase = 2 ⁿ times typical	8s
26h	0000h	Maximum time-out for chip erase = 2 ⁿ times typical	NA

Table 29. Device Geometry Definition

	Offset Word Mode	Data	Description	Value		
27h 0017h Device size = 2^n in number of bytes		0017h	Device size = 2 ⁿ in number of bytes	8 Mbyte		
	28h 29h	0001h 0000h	Flash Device Interface code description	x16 Async.		
	2Ah 2Bh	0003h 0000h	Maximum number of bytes in multi-byte program or page = 2 ⁿ	8		
2Ch 0002h		0002h	Number of Erase Block Regions within the device. It specifies the number of regions within the device containing contiguous Erase Blocks of the same size.	2		
	2Dh 2Eh	007Eh 0000h	3			
40FCT	2Fh 30h	0000h 0001h	Region 1 Information Block size in Region 1 = 0100h * 256 byte	64 Kbyte		
M28W640FCT	31h 0007h 32h 0000h		Region 2 Information Number of identical-size erase block = 0007h+1	8		
	33h 34h	0020h 0000h	Region 2 Information Block size in Region 2 = 0020h * 256 byte	8 Kbyte		
	2Dh 2Eh	0007h 0000h	Region 1 Information Number of identical-size erase block = 0007h+1	8		
40FCB	2Fh 0020h Region 1 Information 30h 0000h Block size in Region 1 = 0020h * 256 byte			8 Kbyte		
M28W640FCB	31h 32h	007Eh 0000h	Region 2 Information Number of identical-size erase block = 007Eh=1	127		
	33h 34h	0000h 0001h	Region 2 Information Block size in Region 2 = 0100h * 256 byte	64 Kbyte		

Table 30. Primary Algorithm-specific Extended Query table

Offset P = 35h ⁽¹⁾	Data	Description	Value
(P+0)h = 35h	0050h		"P"
(P+1)h = 36h	0052h	Primary Algorithm extended Query table unique ASCII string "PRI"	"R"
(P+2)h = 37h	0049h		" "
(P+3)h = 38h	0031h	Major version number, ASCII	"1"
(P+4)h = 39h	0030h	Minor version number, ASCII	"0"
(P+5)h = 3Ah	0066h	Extended Query table contents for Primary Algorithm. Address	
(P+6)h = 3Bh	0000h	(P+5)h contains less significant byte. bit 0Chip Erase supported(1 = Yes, 0 = No)	
(P+7)h = 3Ch	0000h	bit 1Suspend Erase supported(1 = Yes, 0 = No)	No
(P+8)h = 3Dh	0000h	bit 2Suspend Program supported(1 = Yes, 0 = No) bit 3Legacy Lock/Unlock supported(1 = Yes, 0 = No) bit 4Queued Erase supported(1 = Yes, 0 = No) bit 5Instant individual block locking supported(1 = Yes, 0 = No) bit 6Protection bits supported(1 = Yes, 0 = No) bit 7Page mode read supported(1 = Yes, 0 = No) bit 8Synchronous read supported(1 = Yes, 0 = No) bit 31 to 9Reserved; undefined bits are '0'	Yes Yes No No Yes Yes No No
(P+9)h = 3Eh	0001h	Supported Functions after Suspend Read Array, Read Status Register and CFI Query are always supported during Erase or Program operation bit 0Program supported after Erase Suspend (1 = Yes, 0 = No) bit 7 to 1Reserved; undefined bits are '0'	Yes
(P+A)h = 3Fh	0003h	Block Lock Status Defines which bits in the Block Status Register section of the Query are implemented. Address (P+A)h contains less significant byte	
(P+B)h = 40h	0000h	bit 0Block Lock Status Register Lock/Unlock bit active(1 = Yes, 0 = No) bit 1Block Lock Status Register Lock-Down bit active (1 = Yes, 0 = No) bit 15 to 2Reserved for future use; undefined bits are '0'	Yes Yes
(P+C)h = 41h	0030h	V _{DD} Logic Supply Optimum Program/Erase voltage (highest performance) bit 7 to 4HEX value in volts bit 3 to 0BCD value in 100 mV	3V
(P+D)h = 42h	00C0h	V _{PP} Supply Optimum Program/Erase voltage bit 7 to 4HEX value in volts bit 3 to 0BCD value in 100 mV	12V
(P+E)h = 43h	0001h	Number of Protection register fields in JEDEC ID space. "00h," indicates that 256 protection bytes are available	01

Table 30. Primary Algorithm-specific Extended Query table (continued)

Offset P = 35h ⁽¹⁾	Data	Description	Value
(P+F)h = 44h	0080h	Protection Field 1: Protection Description	80h
(P+10)h = 45h	0000h	This field describes user-available One Time Programmable (OTP) Protection register bytes. Some are pre-programmed with device unique serial numbers. Others are user programmable.	00h
(P+11)h = 46h	0003h	bits 0–15 point to the Protection register Lock byte, the section's first byte.	8 byte
(P+12)h = 47h	0004h	The following bytes are factory pre-programmed and user-programmable. bit 0 to 7 Lock/bytes JEDEC-plane physical low address bit 8 to 15Lock/bytes JEDEC-plane physical high address bit 16 to 23 "n" such that 2 ⁿ = factory pre-programmed bytes bit 24 to 31 "n" such that 2 ⁿ = user programmable bytes	16 byte
(P+13)h = 48h		Reserved	

^{1.} See *Table 27*, offset 15 for P pointer definition

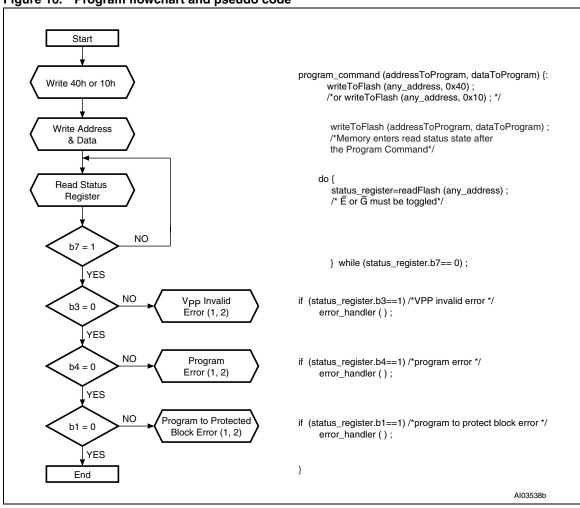
Table 31. Security code area

Offset	Data	Description		
80h	00XX	Protection Register Lock		
81h	XXXX			
82h	XXXX	64 hita uniqua davica number		
83h	XXXX	64 bits: unique device number		
84h	XXXX			
85h	XXXX			
86h	XXXX			
87h	XXXX			
88h	XXXX	100 hita Haar Dragrammahla OTD		
89h	XXXX	128 bits: User Programmable OTP		
8Ah	XXXX			
8Bh	XXXX			
8Ch	XXXX			

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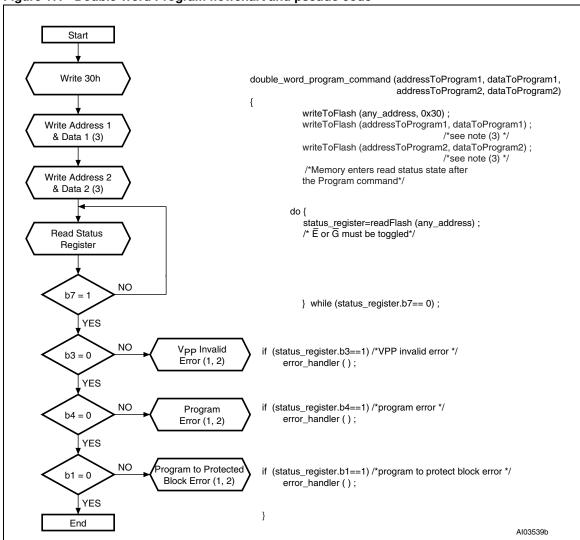
Appendix C Flowcharts and pseudo codes

Figure 16. Program flowchart and pseudo code



- Status check of b1 (Protected Block), b3 (V_{PP} Invalid) and b4 (Program Error) can be made after each program operation or after a sequence.
- 2. If an error is found, the Status Register must be cleared before further Program/Erase Controller operations.

Figure 17. Double Word Program flowchart and pseudo code



- Status check of b1 (Protected Block), b3 (V_{PP} Invalid) and b4 (Program Error) can be made after each program operation or after a sequence.
- 2. If an error is found, the Status Register must be cleared before further Program/Erase operations.
- 3. Address 1 and Address 2 must be consecutive addresses differing only for bit A0.

Start quadruple_word_program_command (addressToProgram1, dataToProgram1, Write 56h addressToProgram2, dataToProgram2, addressToProgram3, dataToProgram3, addressToProgram4, dataToProgram4) { Write Address 1 writeToFlash (any_address, 0x56); & Data 1 (3) writeToFlash (addressToProgram1, dataToProgram1); /*see note (3) */ Write Address 2 writeToFlash (addressToProgram2, dataToProgram2); & Data 2 (3) /*see note (3) */ writeToFlash (addressToProgram3, dataToProgram3); /*see note (3) */ Write Address 3 & Data 3 (3) writeToFlash (addressToProgram4, dataToProgram4); /*see note (3) */ Write Address 4 /*Memory enters read status state after & Data 4 (3) the Program command*/ status_register=readFlash (any_address); Read Status /* E or G must be toggled*/ Register NO b7 = 1} while (status_register.b7== 0); YES NO V_{PP} Invalid if (status_register.b3==1) /*VPP invalid error */ b3 = 0Error (1, 2) error_handler(); YES if (status_register.b4==1) /*program error */ NO Program b4 = 0error_handler(); Error (1, 2) YES NO Program to Protected if (status_register.b1==1) /*program to protect block error */ b1 = 0 Block Error (1, 2) error_handler();

Figure 18. Quadruple Word Program flowchart and pseudo code

 Status check of b1 (Protected Block), b3 (V_{PP} Invalid) and b4 (Program Error) can be made after each program operation or after a sequence.

}

- If an error is found, the Status Register must be cleared before further Program/Erase operations.
- 3. Address 1 to Address 4 must be consecutive addresses differing only for bits A0 and A1.

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YES

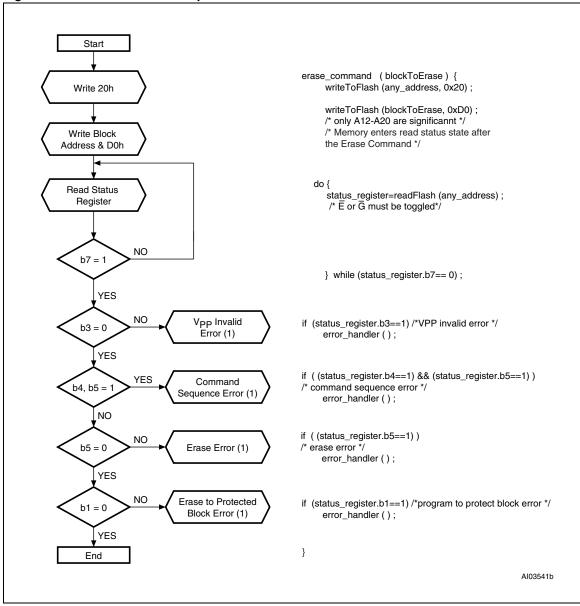
End

Start program_suspend_command () { Write B0h writeToFlash (any_address, 0xB0); writeToFlash (any_address, 0x70); /* read status register to check if program has already completed */ Write 70h status_register=readFlash (any_address); Read Status /* E or G must be toggled*/ Register NO b7 = 1} while (status_register.b7== 0); YES NO Program Complete b2 = 1if (status_register.b2==0) /*program completed */ { writeToFlash (any_address, 0xFF) ; YES read_data (); /*read data from another block*/ /*The device returns to Read Array (as if program/erase suspend was not issued).*/ Write FFh Read data from else another address { writeToFlash (any_address, 0xFF) ; read_data (); /*read data from another address*/ writeToFlash (any_address, 0xD0); /*write 0xD0 to resume program*/ Write D0h Write FFh } Read Data Program Continues AI03540b

Figure 19. Program Suspend & Resume flowchart and pseudo code

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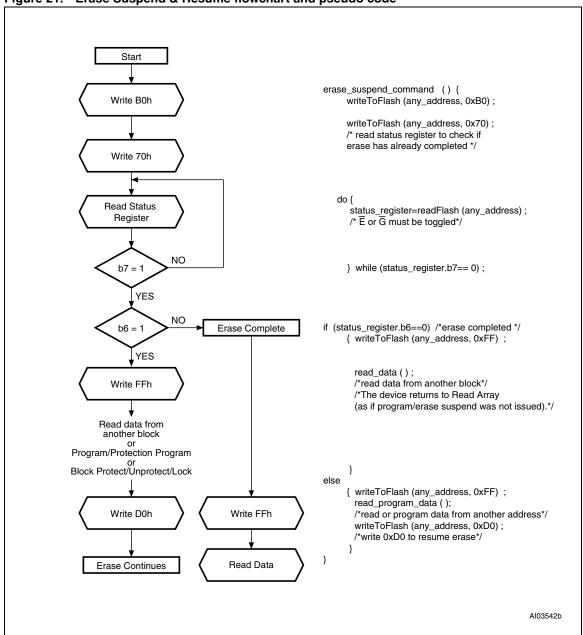
Figure 20. Erase flowchart and pseudo code



1. If an error is found, the Status Register must be cleared before further Program/Erase operations.

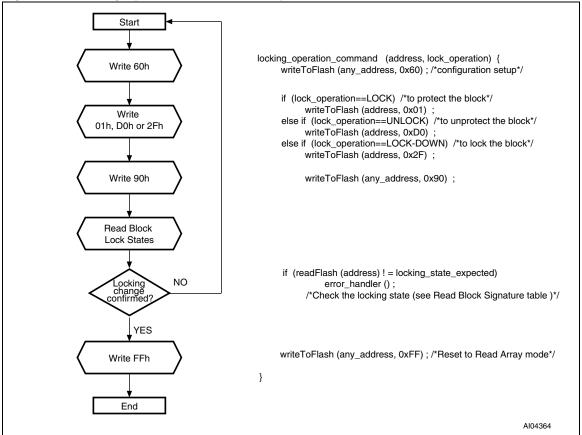
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Figure 21. Erase Suspend & Resume flowchart and pseudo code



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Figure 22. Locking Operations flowchart and pseudo code



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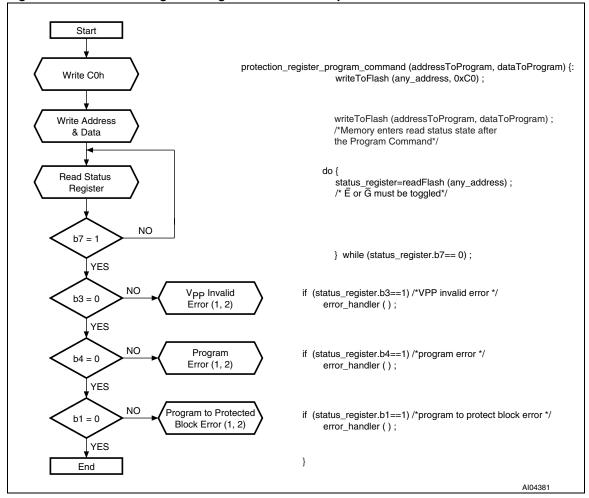


Figure 23. Protection Register Program flowchart and pseudo code

- Status check of b1 (Protected Block), b3 (V_{PP} Invalid) and b4 (Program Error) can be made after each program operation or after a sequence.
- 2. If an error is found, the Status Register must be cleared before further Program/Erase Controller operations.

Appendix D Command Interface and Program/Erase Controller State

Table 32. Write State machine Current/Next⁽¹⁾

	CD	SR bit Read	Command Input (and Next State)								
Current State	bit		Read Array (FFh)	Program Setup (10/40h)	Erase Setup (20h)	Erase Confirm (D0h)	Prog/Ers Suspend (B0h)	Prog/Ers Resume (D0h)	Read Status (70h)	Clear Status (50h)	
Read Array	"1"	Array	Read Array	Prog.Setup	Ers. Setup		Read Array		Read Sts.	Read Array	
Read Status	"1"	Status	Read Array	Program Setup	Erase Setup		Read Array		Read Status	Read Array	
Read Elect.Sg.	"1"	Electronic Signature	Read Array	Program Setup	Erase Setup		Read Array		Read Status	Read Array	
Read CFI Query	"1"	CFI	Read Array	Program Setup	Erase Setup		Read Array			Read Array	
Lock Setup	"1"	Status	Loc	k Command	Error	Lock Lock Cmd Lock (complete)					
Lock Cmd Error	"1"	Status	Read Array	Program Setup	Erase Setup	Head Array			Read Status	Read Array	
Lock (complete)	"1"	Status	Read Array	Program Setup	Erase Setup	Read Array			Read Status	Read Array	
Prot. Prog. Setup	"1"	Status			Pi	rotection Reg	gister Progra	ım			
Prot. Prog. (continue)	"0"	Status			Protec	tion Register	Program co	ontinue			
Prot. Prog. (complete)	"1"	Status	Read Array	Program Setup	Erase Setup		Read Array		Read Status	Read Array	
Prog. Setup	"1"	Status				Prog	ıram				
Program (continue)	"0"	Status		Program	(continue)	Prog. Sus Read Sts	Progra	m (contin	ue)	
Prog. Sus Status	"1"	Status	Prog. Sus Read Array	Program Su Read A		Program (continue)	Prog. Sus Read Array	Program (continue)	Prog. Sus Read Sts	Prog. Sus Read Array	
Prog. Sus Read Array	"1"	Array	Prog. Sus Read Array	Program Suspend to Read Array		Program (continue)	Prog. Sus Read Array	Program (continue)	Prog. Sus Read Sts	Prog. Sus Read Array	
Prog. Sus Read Elect.Sg.	"1"	Electronic Signature	Prog. Sus Read Array	Program Su Read A		Program (continue)	Prog. Sus Read Array	Program (continue)	Prog. Sus Read Sts	Prog. Sus Read Array	

Table 32. Write State machine Current/Next⁽¹⁾ (continued)

	CD		Command Input (and Next State)									
Current State	SR bit 7	Data When Read	Read Array (FFh)	Program Setup (10/40h)	Erase Setup (20h)	Erase Confirm (D0h)	Prog/Ers Suspend (B0h)	Prog/Ers Resume (D0h)	Read Status (70h)	Clear Status (50h)		
Prog. Sus Read CFI	"1"	CFI	Prog. Sus Read Array	Program Su Read A	•	Program (continue)	Prog. Sus Read Array	Program (continue)	Prog. Sus Read Sts	Prog. Sus Read Array		
Program (complete)	"1"	Status	Read Program Erase Array Setup Setup Read Array		Read Status	Read Array						
Erase Setup	"1"	Status	Erase Command Error Erase Erase Continue) Erase Command Error (continue)		Erase Co Er							
Erase Cmd.Error	"1"	Status	Read Program Erase Setup Read Array				Read Array					
Erase (continue)	"0"	Status	Erase (continue)				Erase Sus Read Sts	⊢rase		e (continue)		
Erase Sus Read Sts	"1"	Status	Erase Sus Read Array	Program Setup	Erase Sus Read Array	Erase (continue)	Erase Sus Read Array	Erase (continue)	Erase Sus Read Sts	Erase Sus Read Array		
Erase Sus Read Array	"1"	Array	Erase Sus Read Array	Program Setup	Erase Sus Read Array	Erase (continue)	Erase Sus Read Array	Erase (continue)	Erase Sus Read Sts	Erase Sus Read Array		
Erase Sus Read Elect.Sg.	"1"	Electronic Signature	Erase Sus Read Array	Program Setup	Erase Sus Read Array	Erase (continue)	Erase Sus Read Array	Erase (continue)	Erase Sus Read Sts	Erase Sus Read Array		
Erase Sus Read CFI	"1"	CFI	Erase Sus Read Array	Program Setup	Erase Sus Read Array	Erase (continue)	Erase Sus Read Array	Erase (continue)	Erase Sus Read Sts	Erase Sus Read Array		
Erase (complete)	"1"	Status	Read Array	Program Setup	Erase Setup		Read Array		Read Status	Read Array		

^{1.} Cmd = Command, Elect.Sg. = Electronic Signature, Ers = Erase, Prog. = Program, Prot = Protection, Sus = Suspend.

Table 33. Write State machine Current/Next⁽¹⁾

Table 33.	Command Input (and Next State)						
Current State	Read Elect.Sg. (90h)	Read CFI Query (98h)	Lock Setup (60h)	Prot. Prog. Setup (C0h)	Lock Confirm (01h)	Lock Down Confirm (2Fh)	Unlock Confirm (D0h)
Read Array	Read Elect.Sg.	Read CFI Query	Lock Setup	Prot. Prog. Setup	Read Array		
Read Status	Read Elect.Sg.	Read CFI Query	Lock Setup	Prot. Prog. Setup	Read Array		
Read Elect.Sg.	Read Elect.Sg.	Read CFI Query	Lock Setup	Prot. Prog. Setup	Read Array		
Read CFI Query	Read Elect.Sg.	Read CFI Query	Lock Setup	Prot. Prog. Setup	Read Array		
Lock Setup		Lock Comr	nand Error		Lock (complete)		
Lock Cmd Error	Read Elect.Sg.	Read CFI Query	Lock Setup	Prot. Prog. Setup	Read Array		
Lock (complete)	Read Elect.Sg.	Read CFI Query	Lock Setup	Prot. Prog. Setup	Read Array		
Prot. Prog. Setup	Protection Register Program						
Prot. Prog. (continue)	Protection Register Program (continue)						
Prot. Prog. (complete)	Read Elect.Sg.	Read CFI Query	Lock Setup	Prot. Prog. Setup			
Prog. Setup	Program						
Program (continue)	Program (continue)						
Prog. Suspend Read Status	Prog. Suspend Read Elect.Sg.	Prog. Suspend Read CFI Query	Pro	Program Suspend Read Array			Program (continue)
Prog. Suspend Read Array	Prog. Suspend Read Elect.Sg.	Prog. Suspend Read CFI Query	Program Suspend Read Array Program (continue)			Program (continue)	
Prog. Suspend Read Elect.Sg.	Prog. Suspend Read Elect.Sg.	Prog. Suspend Read CFI Query	Program Suspend Read Array			Program (continue)	
Prog. Suspend Read CFI	Prog. Suspend Read Elect.Sg.	Prog. Suspend Read CFI Query	Program Suspend Bead Array			Program (continue)	

Table 33. Write State machine Current/Next⁽¹⁾ (continued)

Table 33.	Command Input (and Next State)						
Current State	Read Elect.Sg. (90h)	Read CFI Query (98h)	Lock Setup (60h)	Prot. Prog. Setup (C0h)	Lock Confirm (01h)	Lock Down Confirm (2Fh)	Unlock Confirm (D0h)
Program (complete)	Read Elect.Sg.	Read CFIQuery	Lock Setup	Prot. Prog. Setup	Read Array		
Erase Setup	Erase Command Error					Erase (continue)	
Erase Cmd.Error	Read Elect.Sg.	Read CFI Query	Lock Setup	Prot. Prog. Setup	Read Array		
Erase (continue)	Erase (continue)						
Erase Suspend Read Ststus	Erase Suspend Read Elect.Sg.	Erase Suspend Read CFI Query	Lock Setup	Erase Suspend Read Array			Erase (continue)
Erase Suspend Read Array	Erase Suspend Read Elect.Sg.	Erase Suspend Read CFI Query	Lock Setup	Erase S	Erase Suspend Read Array		
Erase Suspend Read Elect.Sg.	Erase Suspend Read Elect.Sg.	Erase Suspend Read CFI Query	Lock Setup	Erase Suspend Read Array			Erase (continue)
Erase Suspend Read CFI Query	Erase Suspend Read Elect.Sg.	Erase Suspend Read CFI Query	Lock Setup	Frace Suchend Read Array			Erase (continue)
Erase (complete)	Read Elect.Sg.	Read CFI Query	Lock Setup	Prot. Prog. Setup	♥ I Read Δrrav		

 $^{1. \}quad \mathsf{Cmd} = \mathsf{Command}, \ \mathsf{Elect.Sg.} = \mathsf{Electronic} \ \mathsf{Signature}, \ \mathsf{Prog.} = \mathsf{Program}, \ \mathsf{Prot} = \mathsf{Protection}.$

Revision history

Table 34. Document revision history

Date	Version	Revision details	
24-May-2004	0.1	First Issue	
23-Aug-2004	0.2	Figure 2: TSOP connections and Figure 3: TFBGA connections (top view through package) updated.	
08-Apr-2005	1.0	Datasheet maturity changed to PRELIMINARY DATA. TSOP48 Package Mechanical Data updated in <i>Table 20: TSOP48 - 48 lead Plastic Thin Small Outline, 12 x 20mm, package mechanical data.</i>	
21-Aug-2006	2	Document status promoted from Preliminary Data to full Datasheet. t _{GLQV} value changed for 100ns speed class (codified as 10 in part numbering scheme) in <i>Table 16: Read AC characteristics</i> . Blank and T options removed from below <i>Option</i> in <i>Table 22</i> and <i>Table 23</i> . Packages are ECOPACK® compliant.	
23-Oct-2006	3	The 0.13µm technology was removed from the device options of <i>Table 22: Ordering information scheme</i> .	
26-Mar-2008	4	Applied Numonyx branding.	

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